XC9147/XC9148 Series

ETR04028-004a

Highly functionality, 1.4A Step-up DC/DC Converters

☆Green Operation compatible

■GENERAL DESCRIPTION

XC9147/XC9148 series are synchronous step-up DC/DC converters with a 0.17Ω Nch driver FET and a 0.2Ω synchronous Pch switching FET built-in.

The series are able to start operation from an input voltage of 0.9V, suitable for equipment using single Alkaline battery or Nickel metal hydride battery.

The output voltage can be set from 1.8V to 5.5V in steps of 0.1V.

During the devices enter stand-by mode, A/D/G/J types prevent the application malfunction by C_L Discharge function which can quickly discharge the electric charge at the output capacitor (C_L). B/E/H/K types are able to allow the drive of subsequent devices by the bypass function which maintain continuity between the input and output. C/F/M/L types are able to connect in parallel with other power supplies by Load Disconnection function which breaks continuity between the input and output.

G/H/M/J/K/L types are able to stop the operation of the IC and reduce leakage of alkaline batteries when the battery voltage drops by the UVLO function. The release voltage of UVLO is 1.6V.

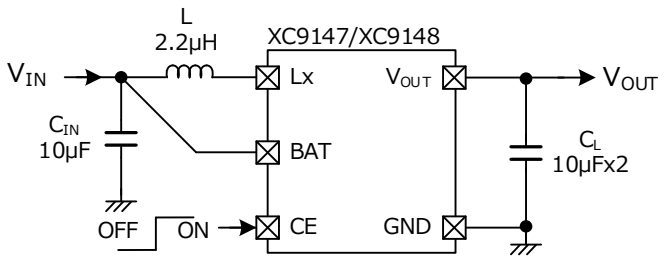
■APPLICATIONS

- ●Portable equipment
- ●Beauty & health equipment
- ●Wearable devices
- ●Game & Hobby
- ●PC Peripherals
- ●Devices with 1~3 Alkaline, 1~3 Nickel Hydride, 1 Lithium and 1 Li-ion

■FEATURES

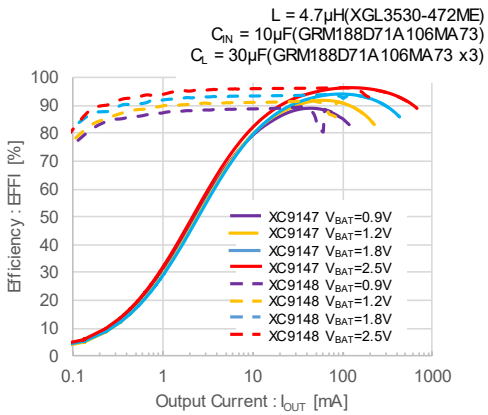
Input Voltage Range	: 0.65V ~ 6.0V (Operation start voltage : 0.9V)
Fixed Output Voltage	: 1.8V ~ 5.5V (A,B,C type)
	: 2.2V ~ 5.5V (except A,B,C type)
Oscillation Frequency	: 1.2MHz, 3.0MHz
Output Current	: 750mA @V_{OUT}=5.0V, V_{BAT}=3.3V
	500mA @V_{OUT}=3.3V, V_{BAT}=1.8V
Control Mode Selection	: PWM (XC9147)
	PWM/PFM (XC9148)
Load Transient Response	: 100mV@V_{OUT}=3.3V, V_{BAT}=1.8V, f_{osc}=3.0MHz
	I_{OUT}=1mA→200mA (tr=5μs)
Protection Function	: Thermal shutdown
	Current limit
	Integral latch method (D/E/F/J/K/L types)
	Short circuit protection (D/E/F/J/K/L types)
	UVLO (G/H/M/J/K/L types)
Functions	: Soft-start
	Load Disconnection (A/C/D/F/G/M/J/L types)
	C_L Discharge (A/D/G/J types)
	Bypass Switch (XC9148B/E/H/K types)
Output Capacitor	: Ceramic Capacitor
Operating Ambient Temperature	: -40℃ ~ 105℃
Package	: USP-6C (1.8x2.0x0.6mm)
	SOT-89-5 (4.5x4.6x1.6mm)
Environmentally Friendly	: EU RoHS Compliant, Pb Free

■TYPICAL APPLICATIONS CIRCUIT



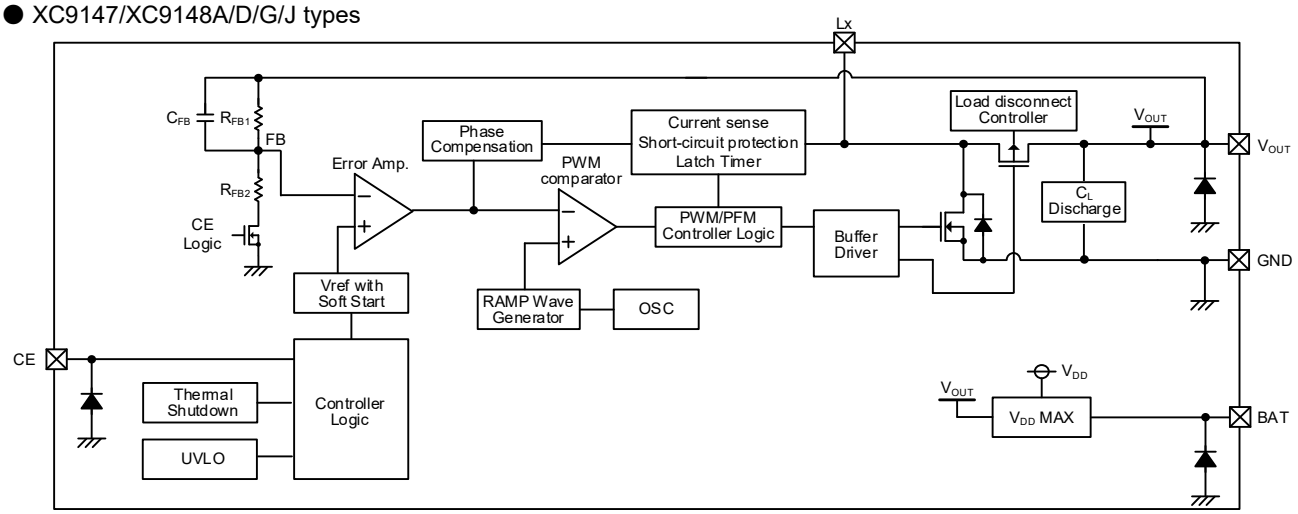
■TYPICAL PERFORMANCE CHARACTERISTICS

$V_{OUT(T)}$=3.3V, f_{osc}=1.2MHz



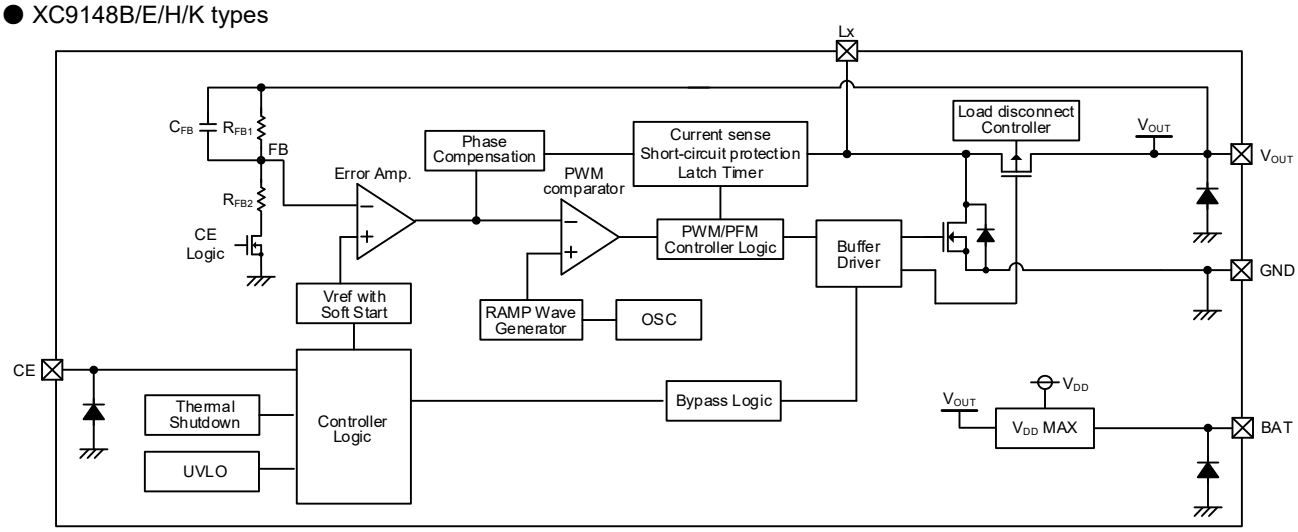
■BLOCK DIAGRAM

● XC9147/XC9148A/D/G/J types



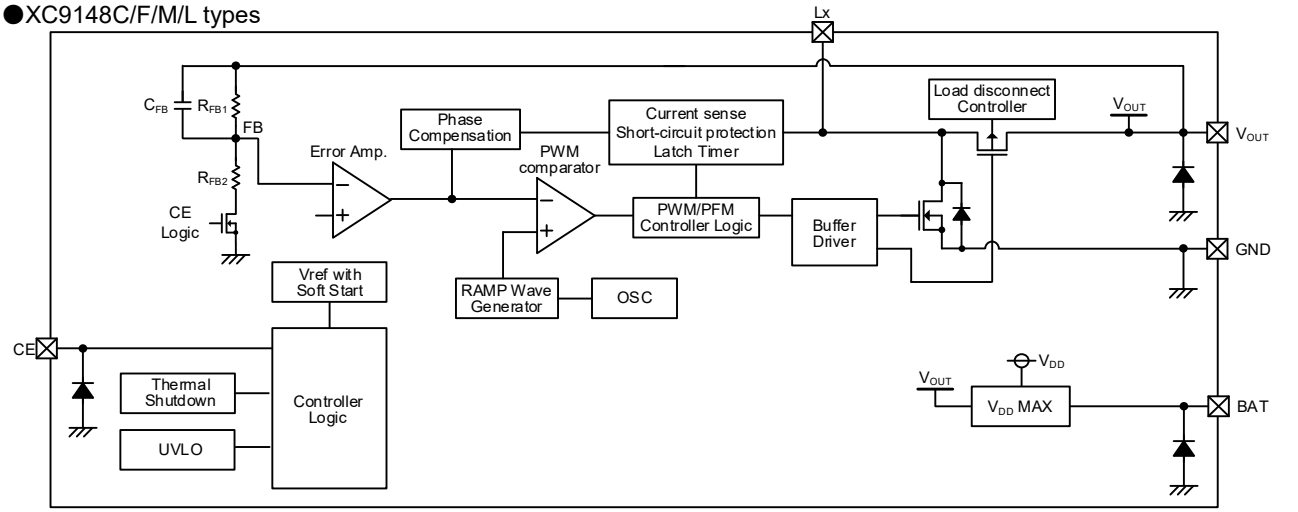
* Diodes inside the circuits are ESD protection diodes and parasitic diodes.
XC9147 series chooses only PWM control.
UVLO / short circuit protection / integral latch can be selected according to the types.

● XC9148B/E/H/K types



* Diodes inside the circuits are ESD protection diodes and parasitic diodes.
UVLO / short circuit protection / integral latch can be selected according to the types.

●XC9148C/F/M/L types



* Diodes inside the circuits are ESD protection diodes and parasitic diodes.
UVLO / short circuit protection / integral latch can be selected according to the types.

■PRODUCT CLASSIFICATION

●Ordering Information

XC9147①②③④⑤⑥-⑦ : PWM Control

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Type	A	Refer to Selection Guide
		D	
		G	
		J	
②③	Output Voltage (A Type)	18 ~ 55	Output Voltage : e.g. V_{OUT}=1.8V⇒②=1, ③=8 Output Voltage Range: 1.8V~5.5V (0.1V increments)
	Output Voltage (D/G/J Type)	22 ~ 55	Output Voltage : e.g. V_{OUT}=2.5V⇒②=2, ③=5 Output Voltage Range: 2.2V~5.5V (0.1V increments)
④	Oscillation Frequency	C	1.2MHz
		D	3.0MHz
⑤⑥-⑦(*1)	Packages (Order Unit)	PR-G	SOT-89-5 (1,000pcs/Reel)
		ER-G	USP-6C (3,000pcs/Reel)

(*1) The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully EU RoHS compliant.

●Selection guides

TYPE	Purpose	UVLO	C_L Discharge	Current Limit	Short Protection	Stand-by Options at CE="L"
A(*2)	Load Disconnection	-	Yes	Yes (Without latch)	-	Complete Output Disconnect
D				Yes (With integral latch)	Yes	
G(*2)		Yes		Yes (Without latch)	-	
J				Yes (With integral latch)	Yes	

(*2) A, G type is the standard type.

■PRODUCT CLASSIFICATION

●Ordering Information

XC9148①②③④⑤⑥-⑦ : PWM/PFM automatic switching control

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Type	A	Refer to Selection Guide
		B	
		C	
		D	
		E	
		F	
		G	
		H	
		M	
		J	
		K	
		L	
②③	Output Voltage (A/B/C Type)	18 ~ 55	Output Voltage : e.g. V_{OUT}=1.8V⇒②=1, ③=8 Output Voltage Range: 1.8V~5.5V (0.1V increments)
	Output Voltage (D/E/F/G/H/M/J/K/L Type)	22 ~ 55	Output Voltage : e.g. V_{OUT}=2.5V⇒②=2, ③=5 Output Voltage Range: 2.2V~5.5V (0.1V increments)
④	Oscillation Frequency	C	1.2MHz
		D	3.0MHz
⑤⑥-⑦(*1)	Packages (Order Unit)	PR-G	SOT-89-5 (1,000pcs/Reel)
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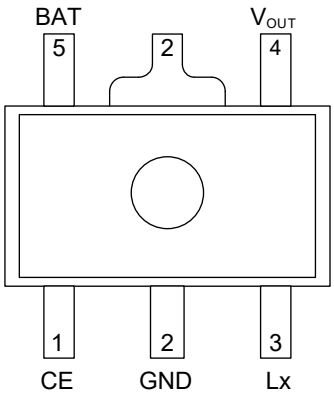
●Selection guides

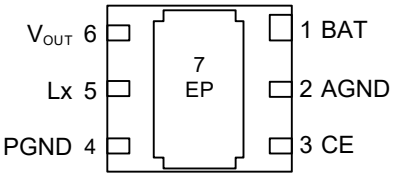
TYPE	Purpose	UVLO	C_L Discharge	Current Limit	Short Protection	Stand-by Options at CE="L"
A (*2)	Load Disconnection	-	Yes	Yes (Without latch)	-	Complete Output Disconnect
D				Yes (With integral latch)	Yes	
G (*2)		Yes		Yes (Without latch)	-	
J				Yes (With integral latch)	Yes	
B (*2)	Bypass Mode at CE="L"	-	-	Yes (Without latch)	-	Input-to-Output Bypass
E				Yes (With integral latch)	Yes	
H (*2)		Yes		Yes (Without latch)	-	
K				Yes (With integral latch)	Yes	
C (*2)	V_{OUT} OR Connection	-	-	Yes (Without latch)	-	Complete Output Disconnect
F				Yes (With integral latch)	Yes	
M		Yes		Yes (Without latch)	-	
L				Yes (With integral latch)	Yes	

(*2) A, B, C, G, H type is the standard type.

■PIN CONFIGURATION



SOT-89-5
(TOP VIEW)



USP-6C
(BOTTOM VIEW)

■PIN ASSIGNMENT

PIN NUMBER		PIN NAME	FUNCTIONS
SOT-89-5	USP-6C		
1	3	CE	Chip Enable
2	-	GND	Ground
5	1	BAT	Power Input
4	6	V_{OUT}	Output Voltage
3	5	Lx	Switching
-	2	AGND	Analog Ground
-	4	PGND	Power Ground
-	7	EP	Exposed thermal pad. The Exposed pad must be connected to GND(Pin2,4).

■FUNCTION CHART

PIN NAME	SIGNAL	STATUS
CE	L	Stand-by
	H	Active
	OPEN	Undefined State (*1)

(*1) Do not leave the CE pin open.

■ABSOLUTE MAXIMUM RATINGS

Ta=25℃

PARAMETER		SYMBOL	RATINGS	UNITS
BAT Pin Voltage		V_{BAT}	-0.3 ~ 7.0	V
Lx Pin Voltage		V_{Lx}	-0.3 ~ 7.0	V
V_{OUT} Pin Voltage		V_{OUT}	-0.3 ~ 7.0	V
CE Pin Voltage		V_{CE}	-0.3 ~ 7.0	V
Power Dissipation (Ta=25℃)	SOT-89-5	Pd	1750 (JESD51-7 board) (*1)	mW
	USP-6C		1250 (JESD51-7 board) (*1)	
Junction Temperature		Tj	-40 ~ 125	℃
Storage Temperature		Tstg	-55 ~ 125	℃

GND(AGND,PGND) are standard voltage for all of the voltages.

(*1) The power dissipation figure shown above is based upon PCB mounted and it is for reference only.
Please refer to PACKAGING INFORMATION for the mounting condition.

■RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Input Voltage	V_{BAT}	-	-	6.0	V
Applied voltage to V_{OUT} (*1)	V_{OUT}	$V_{OUT(T)}$	-	6.0	V
Lx Pin Current (*2)	I_{LX}	-	-	3.5	A
CE Pin Voltage	V_{CE}	0.0	-	6.0	V
Operating Ambient Temperature	Topr	-40	-	105	℃
Input Capacitor (Effective Value)	C_{IN}	3.3 (*3)	-	1000 (*4)	μF

GND(AGND,PGND) are standard voltage for all of the voltage.

$V_{OUT(T)}$: Target Output voltage

(*1) Depending on the type of product and operation mode, some external voltages cannot be applied to the output side. Regarding to support for OR connection or not, please refer to the operational explanation and NOTES ON USE.

(*2) Due to the Lx pin current, the junction temperature may cross over the maximum junction temperature. Please use within the range that does not cross over the maximum junction temperature.

(*3) Some ceramic capacitors have an effective capacitance that is significantly lower than the nominal value due to the applied DC bias and ambient temperature. For the input / output capacitance of this IC, use an appropriate ceramic capacitor according to the DC bias usage conditions (ambient temperature, input / output voltage) so that the effective capacitance value is equal to or higher than the recommended component.

(*4) If using a large-capacity capacitor such as an electrolytic capacitor or tantalum capacitor as the input capacitance, place a low ESR ceramic capacitor in parallel. If a ceramic capacitor is not placed, high-frequency voltage fluctuations will increase and the IC may malfunction.

■ELECTRICAL CHARACTERISTICS

Ta=25℃

PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNITS	CIRCUIT
Input Voltage	V_{IN}			-	-	6.0	V	①
Output Voltage	V_{OUT}	Voltage to start oscillation while $V_{OUT}=V_{OUT(T)}$ ×1.03→$V_{OUT(T)}$×0.97		<E-1>	<E-2>	<E-3>	V	⑤
Operation Start Voltage	V_{ST1}	R_L=OPEN	A/B/C/D/E/F Type	-	-	0.90	V	①
Operation Hold Voltage	V_{HLD}	R_L=OPEN	A/B/C/D/E/F Type	-	0.65	-	V	①
Quiescent Current (XC9148)	Iq	$V_{BAT}=V_{OUT(T)}$+0.2V $V_{OUT}=V_{OUT(T)}$+0.5V	f_{OSC}=1.2MHz	-	19.0	38.0	μA	③
			f_{OSC}=3.0MHz	-	30.0	48.0		
Input Pin Quiescent Current	Iq_bat	V_{BAT}= $V_{OUT(T)}$-0.2V, V_{OUT}= $V_{OUT(T)}$+0.5V	XC9148 C/F	-	0.12	0.36	μA	③
			XC9148 M/L	-	1.20	2.06		
Oscillation Frequency	f_{OSC}	V_{BAT}=1.7V, V_{OUT}=1.7V	f_{OSC}=1.2MHz	1.02	1.20	1.38	MHz	⑤
			f_{OSC}=3.0MHz	2.40	3.00	3.60		
Maximum Duty Cycle	D_{MAX}	V_{BAT}=1.7V, V_{OUT}=1.7V	f_{OSC}=1.2MHz	85	95	98	%	⑤
			f_{OSC}=3.0MHz	83	93	98		
Minimum Duty Cycle	D_{MIN}	$V_{OUT}=V_{BAT}$= $V_{OUT(T)}$+0.5V		-	-	0	%	⑤
PFM Switching Current (XC9148)	I_{PFM}	V_{BAT}=1.7V, R_L: OPEN	f_{OSC}=1.2MHz	-	280	450	mA	①
			f_{OSC}=3.0MHz	-	280	500		
Efficiency (XC9148)	EFFI	V_{BAT}= $V_{OUT(T)}$×0.6, R_L: Refer to Table 1		-	86(*3)	-	%	①
Efficiency	EFFI	V_{BAT}= $V_{OUT(T)}$ ×0.6, I_{OUT}= 100mA		-	90(*3)	-		
Stand-by Current	I_{STB}	$V_{BAT}=V_{Lx}$=6.0V, V_{CE}=0.0V(*1)	A/D/G/J Type	-	0.0	1.0	μA	⑧
			B/E/H/K Type	-	0.0	1.0	μA	⑦
			C/F/M/L Type	-	0.16	1.0	μA	⑧
Lx SW "Nch" ON Resistance	R_{LXN}	V_{BAT}=3.3V, V_{OUT}=1.7V		-	0.17 (*3)	-	Ω	-
Lx SW "Pch" ON Resistance	R_{LXP}	$V_{BAT}=V_{Lx}$=3.3V, I_{OUT}=200mA		-	0.2 (*2)	-	Ω	④
Lx SW "H" Leakage Current	I_{LXLH}	V_{BAT}=6.0V, V_{CE}=0V, V_{Lx}=6.0V(*1)	A/C/D/F/G/M/J/L Type	-	0.0	1.0	μA	⑧
			B/E/H/K Type					⑦
Lx SW "L" Leakage Current (XC9148 C/F/M/L)	I_{LXLL}	V_{BAT}=0.0V, V_{CE}=0.0V, V_{Lx}=0.0V,V_{OUT}=6.0V		-	0.0	1.0	μA	②
Current Limit	I_{LIM}	V_{BAT}= $V_{OUT(T)}$-0.2V, R_{Lx}=0.5Ω		<E-4>	<E-5>	<E-6>	A	⑥
Integral Latch Time (D/E/F/J/K/L Type)	t_{LAT}	V_{BAT}= $V_{OUT(T)}$-0.3V, R_{Lx}=0.5Ω, Time from current limit start to stop Lx oscillation	f_{OSC}=1.2MHz	45	200	450	μs	⑥
			f_{OSC}=3.0MHz	25	100	200		
Latch Release Voltage (D/E/F Type)	V_{LAT_R}	After the integral latch was operated, R_L:OPEN, $V_{BAT}=V_{OUT(T)}$-0.2V→0.9V		0.9	1.2	1.5	V	①
Short-circuit Protection Threshold Voltage (D/E/F/J/K/L Type)	V_{SHORT}	$V_{BAT}=V_{OUT(T)}$-0.2V, R_L=0Ω		-	V_{BAT}(*3)	-	V	①

■ELECTRICAL CHARACTERISTICS (Continued)

Ta=25℃

PARAMETER	SYMBOL	CONDITIONS		MIN.	TYP.	MAX.	UNITS	CIRCUIT
Soft-Start Time	t_{SS}	V_{BAT}= $V_{OUT(T)}$×0.85, V_{OUT} =$V_{OUT(T)}$× 0.9, After "H" is fed to CE, the time by when clocks are generated at Lx pin.	f_{OSC}=1.2MHz	0.6	1.2	2.5	ms	⑤
			f_{OSC}=3.0MHz	0.2	0.5	1.0		
C_L Discharge Resistance (A/D/G/J Type)	R_{DCHG}	V_{BAT}= 3.3V, V_{OUT}=3.3V, V_{CE}=0V		100	180	400	Ω	②
CE "H" Voltage	V_{CEH}	V_{OUT}= $V_{OUT(T)}$-0.15V, Applied voltage to V_{CE}, Voltage changes Lx to be generated.	Ta=25℃	0.80	-	6.00	V	⑤
			Ta=-40~105℃(*3)	0.80	-	6.00		
CE "L" Voltage	V_{CEL}	V_{OUT}= $V_{OUT(T)}$-0.15V, Applied voltage to V_{CE}, Voltage changes Lx to "H" level	Ta=25℃	GND	-	0.20	V	⑤
			Ta=-40~105℃(*3)	GND	-	0.20		
CE "H" Current	I_{CEH}	V_{BAT}=6.0V,V_{OUT}=6.0V, V_{Lx}=6.0V,V_{CE}=6.0V		-0.1	0.0	0.1	μA	②
CE "L" Current	I_{CEL}	V_{BAT}=6.0V,V_{OUT}=6.0V, V_{Lx}=6.0V,V_{CE}=0.0V		-0.1	0.0	0.1	μA	②
Thermal Shutdown Temperature	T_{TSD}			-	150	-	℃	-
Hysteresis Width	T_{HYS}			-	25	-	℃	-
UVLO Release Voltage (G/H/M/J/K/L Type)	V_{UVLO_R}	R_L=1kΩ, While V_{IN}=0.2V→1.8V, Voltage to start oscillation		1.40	1.60	1.73	V	①
UVLO Hysteresis Width (G/H/M/J/K/L Type)	V_{UVLO_HYS}			0.070	0.150	0.215	V	①
UVLO Detect Delay (G/H/M/J/K/L Type)	t_{DF}	After V_{IN}=($V_{OUT(T)}$+V_{UVLO_R})/2→ 0.65V, time to stop oscillation	f_{OSC}=1.2MHz	55	200	425	μs	①
			f_{OSC}=3.0MHz	35	100	230		

Test conditions : unless otherwise stated, V_{BAT}=1.5V, V_{CE}=3.3V, Lx=OPEN, R_{Lx}=56Ω

$V_{OUT(T)}$: Target voltage

(*1) A/C/D/F/G/M/J/L types : V_{OUT}=0.0V
B/E/H/K types : V_{OUT}=OPEN

(*2) Design value of A/C/D/F/G/M/J/L types

(*3) Design value

Table 1. External Components R_L Table

$V_{OUT(T)}$	R_L
1.8V≦$V_{OUT(T)}$<2.1V	150Ω
2.1V≦$V_{OUT(T)}$<3.1V	220Ω
3.1V≦$V_{OUT(T)}$<4.3V	330Ω
4.3V≦$V_{OUT(T)}$≦5.5V	470Ω

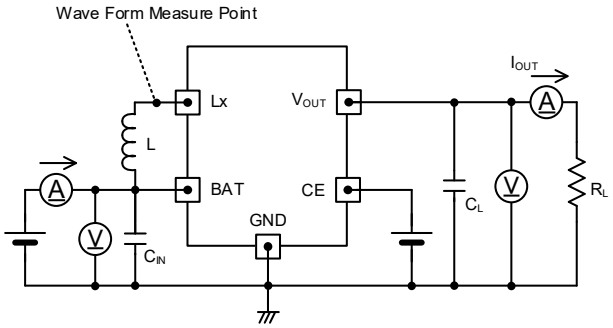
■ELECTRICAL CHARACTERISTICS (Continued)

Table 2. SPEC Table

NOMINAL OUTPUT VOLTAGE	V_{OUT}			I_{LIM}		
	<E-1>	<E-2>	<E-3>	<E-4>	<E-5>	<E-6>
UNITS	V	V	V	A	A	A
$V_{OUT(T)}$	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
1.8	1.764	1.800	1.836	-	1.28	3.10
1.9	1.862	1.900	1.938	-	1.47	3.10
2.0	1.960	2.000	2.040	-	1.65	3.10
2.1	2.058	2.100	2.142	-	1.81	3.10
2.2	2.156	2.200	2.244	-	1.95	3.10
2.3	2.254	2.300	2.346	-	2.07	3.10
2.4	2.352	2.400	2.448	-	2.17	3.10
2.5	2.450	2.500	2.550	-	2.26	3.10
2.6	2.548	2.600	2.652	-	2.32	3.10
2.7	2.646	2.700	2.754	-	2.37	3.10
2.8	2.744	2.800	2.856	-	2.40	3.10
2.9	2.842	2.900	2.958	-	2.41	3.10
3.0	2.940	3.000	3.060	1.52	2.42	3.10
3.1	3.038	3.100	3.162	1.52	2.42	3.10
3.2	3.136	3.200	3.264	1.52	2.42	3.10
3.3	3.234	3.300	3.366	1.53	2.42	3.10
3.4	3.332	3.400	3.468	1.53	2.42	3.10
3.5	3.430	3.500	3.570	1.54	2.42	3.10
3.6	3.528	3.600	3.672	1.54	2.42	3.10
3.7	3.626	3.700	3.774	1.54	2.42	3.10
3.8	3.724	3.800	3.876	1.55	2.42	3.10
3.9	3.822	3.900	3.978	1.55	2.42	3.10
4.0	3.920	4.000	4.080	1.55	2.42	3.10
4.1	4.018	4.100	4.182	1.56	2.42	3.10
4.2	4.116	4.200	4.284	1.56	2.42	3.10
4.3	4.214	4.300	4.386	1.57	2.42	3.10
4.4	4.312	4.400	4.488	1.57	2.42	3.10
4.5	4.410	4.500	4.590	1.57	2.42	3.10
4.6	4.508	4.600	4.692	1.58	2.42	3.10
4.7	4.606	4.700	4.794	1.58	2.42	3.10
4.8	4.704	4.800	4.896	1.58	2.42	3.10
4.9	4.802	4.900	4.998	1.59	2.42	3.10
5.0	4.900	5.000	5.100	1.59	2.42	3.10
5.1	4.998	5.100	5.202	1.59	2.42	3.10
5.2	5.096	5.200	5.304	1.60	2.42	3.10
5.3	5.194	5.300	5.406	1.60	2.42	3.10
5.4	5.292	5.400	5.508	1.61	2.42	3.10
5.5	5.390	5.500	5.610	1.61	2.42	3.10

■TEST CIRCUITS

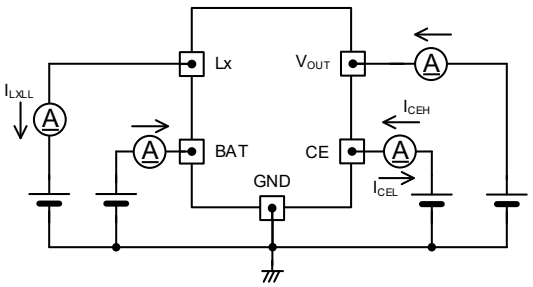
< Circuit No.① >



※External Components
C_{IN} : 10μF(ceramic)

f_{OSC} = 1.2MHz
L : 4.7μH, C_L : 30μF(ceramic)
f_{OSC} = 3.0MHz
L : 2.2μH, C_L : 20μF(ceramic)

< Circuit No.② >



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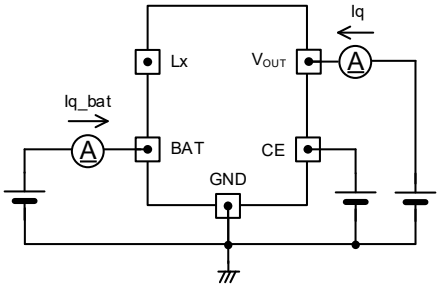

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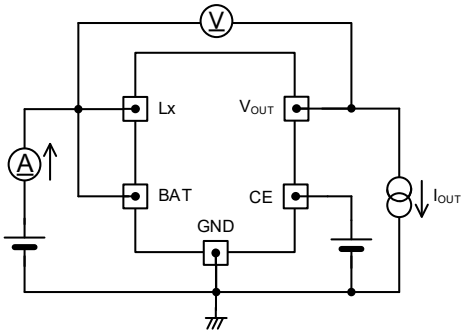

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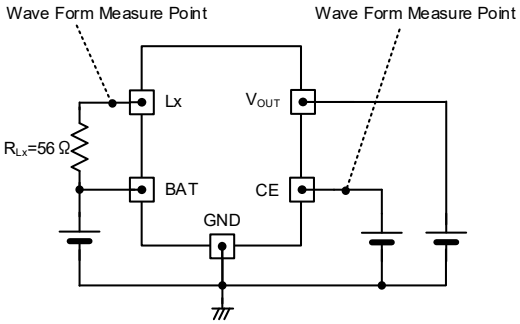

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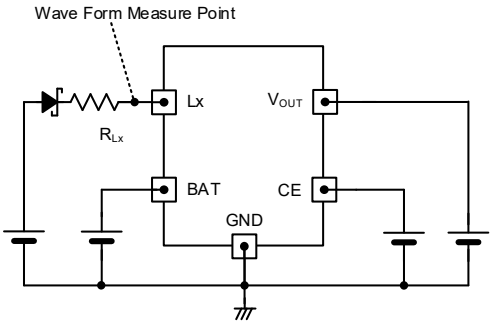

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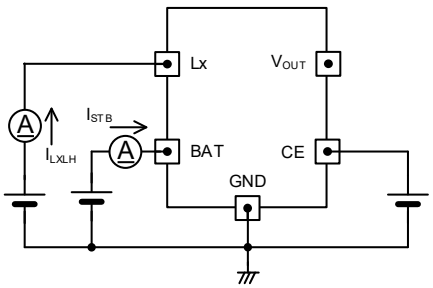

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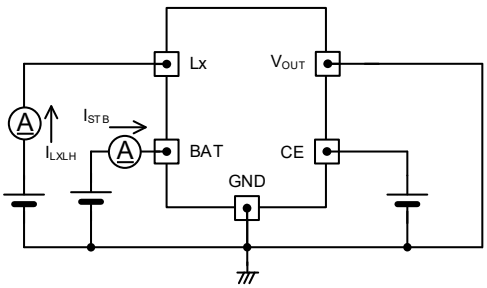
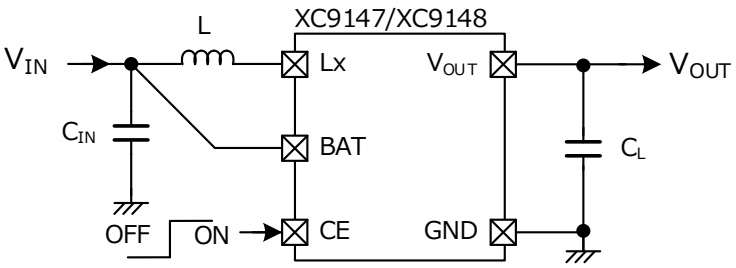


■TYPICAL APPLICATION CIRCUIT / PARTS SELECTION GUIDE



【Typical Examples】f_{OSC}=1.2MHz

	CONDITIONS	MANUFACTURER	PRODUCT NUMBER	VALUE	SIZE(L×W×T)
L	-	Murata	DFE252012F-4R7M=P2	4.7μH	2.5x2.0x1.2mm
		Coilcraft	XGL3530-472ME	4.7μH	3.5x3.2x3.0mm
			XFL4020-472ME	4.7μH	4.0x4.0x2.1mm
C_{IN}(*1)	-	Murata	GRM188D71A106MA73	10μF/10V	1.6x0.8x0.8mm
C_L(*2)	Input Current≦1.0A	Murata	GRM188D71A106MA73	10μF/10V x 2	1.6x0.8x0.8mm
	1.0A< Input Current	Murata	GRM188D71A106MA73	10μF/10V x 3	1.6x0.8x0.8mm

【Typical Examples】f_{OSC}=3.0MHz

	CONDITIONS	MANUFACTURER	PRODUCT NUMBER	VALUE	SIZE(L×W×T)
L	-	TDK	TFM201610ALM-2R2MTAA	2.2μH	2.0x1.6x1.0mm
		Murata	DFE252012F-2R2M=P2	2.2μH	2.5x2.0x1.2mm
		Coilcraft	XGL3520-222ME	2.2μH	3.5x3.2x2.0mm
			XFL4020-222ME	2.2μH	4.0x4.0x2.1mm
C_{IN}(*1)	-	Murata	GRM188D71A106MA73	10μF/10V	1.6x0.8x0.8mm
C_L(*2)	Input Current≦1.0A	Murata	GRM188D71A106MA73	10μF/10V	1.6x0.8x0.8mm
	1.0A< Input Current	Murata	GRM188D71A106MA73	10μF/10V x 2	1.6x0.8x0.8mm

(*1) Use an appropriate ceramic capacitor according to the DC bias usage conditions (ambient temperature, input / output voltage) so that the effective capacitance value is equal to or higher than the recommended component.

(*2) If a tantalum or low ESR electrolytic capacitor is used for the C_L, the ripple voltage will increase.
When using an electrolytic capacitor for the C_L, connect a ceramic capacitor in parallel before use.

In addition, when a large-capacity ceramic capacitor, tantalum, low ESR electrolytic capacitor, etc. are used for the C_L, the following operations may occur.

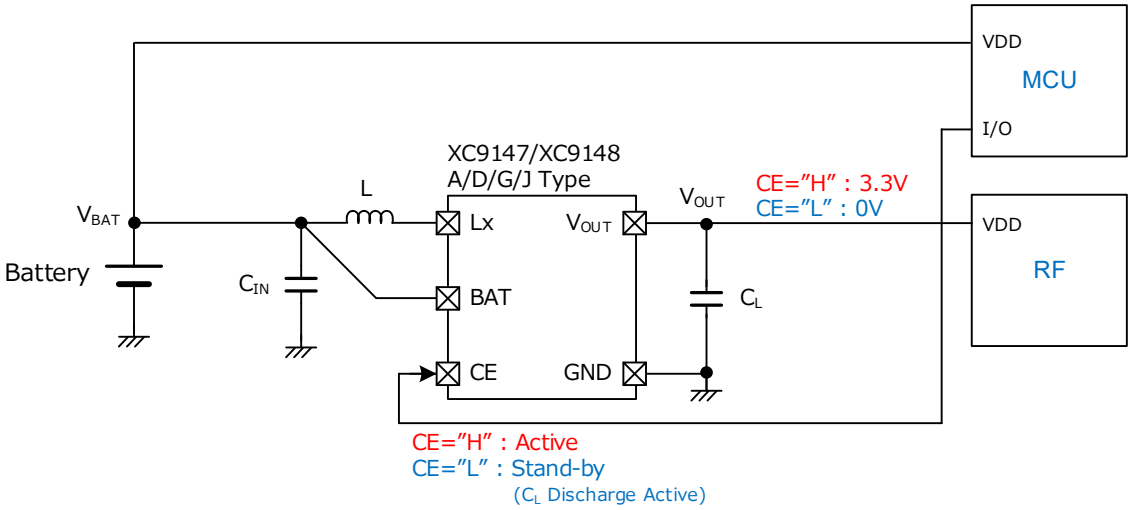
(a) The output voltage may become unstable under heavy load.

(b) For products with an integral latch, the integral latch function may operate and the output voltage may not rise to the target voltage if the current limit function continues after the start mode is completed.

■TYPICAL APPLICATION CIRCUIT/PARTS SELECTION GUIDE

＜Load disconnection function : A/D/G/J types＞

It is configured to cut off the continuity from the input side to the output side during standby mode (CE = ”L”).
For the A/D/G/J types, the C_L discharge function operates when the charge in the output capacitance is quickly discharged. In order to prevent the application from malfunction, the charge remaining in the output capacitance.

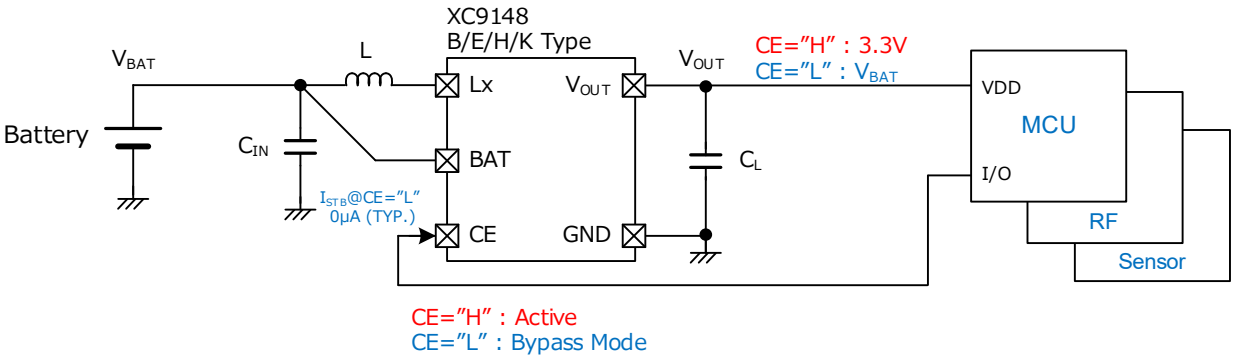


＜Bypass mode: XC9148 B/E/H/K types＞

The Pch synchronous switching FET is turned on to connect the input side and output side during the standby mode (CE = ”L”),. By operating in this bypass mode, current can be supplied to the output side even during standby mode, and it is possible to drive the subsequent devices.

In this configuration, a system that can be driven by a low voltage at the standby or sleep mode, it is set to bypass mode and the input voltage is output to the output side. where communication or calculation that requires a high drive voltage is performed in the active mode, the system is driven by activating of the IC and performing boosting operation.

This operation can dramatically reduce the power consumption in the standby mode and improve the battery life.



■TYPICAL APPLICATION CIRCUIT/PARTS SELECTION GUIDE

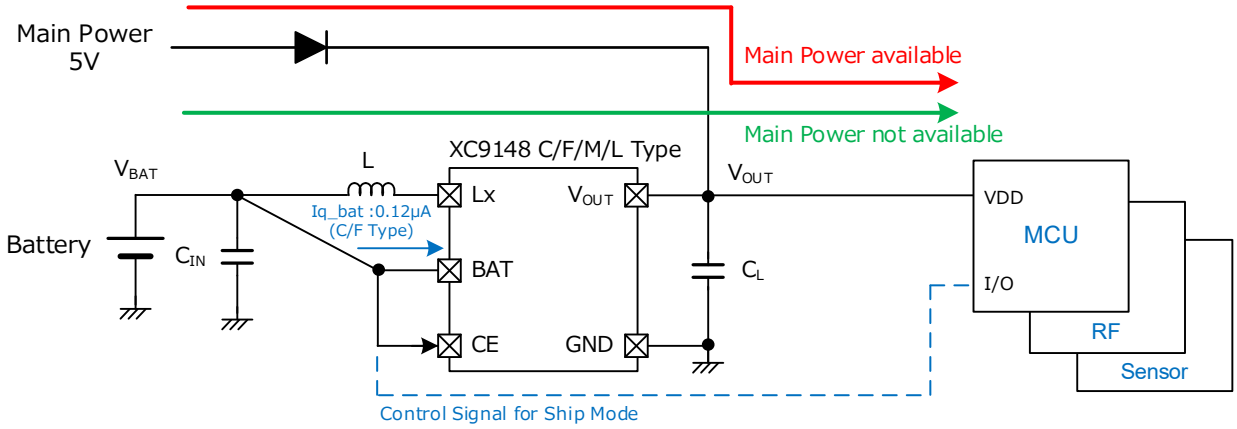
＜OR connection: XC9148 C/F/M/L types＞

The XC9148 C/F/M/L types compare the input voltage BAT and output voltage V_{OUT} to optimally control the orientation of the parasitic diode of the Pch synchronous switching FET even during standby mode, so that the input side and output side do not connect through the parasitic diode of the Pch synchronous switching FET.

Even if an external voltage higher than the BAT voltage is applied to the output side by controlling this parasitic diode, the input side and output side do not connect, and output OR connection is possible.

This type can be used for OR connection is possible such as backup power supply and output OR connection assuming the input of an external power supply.

Moreover, the design which suppresses the discharge current from a battery at the time of OR connection is adopted. This can suppress battery discharge during OR connection.



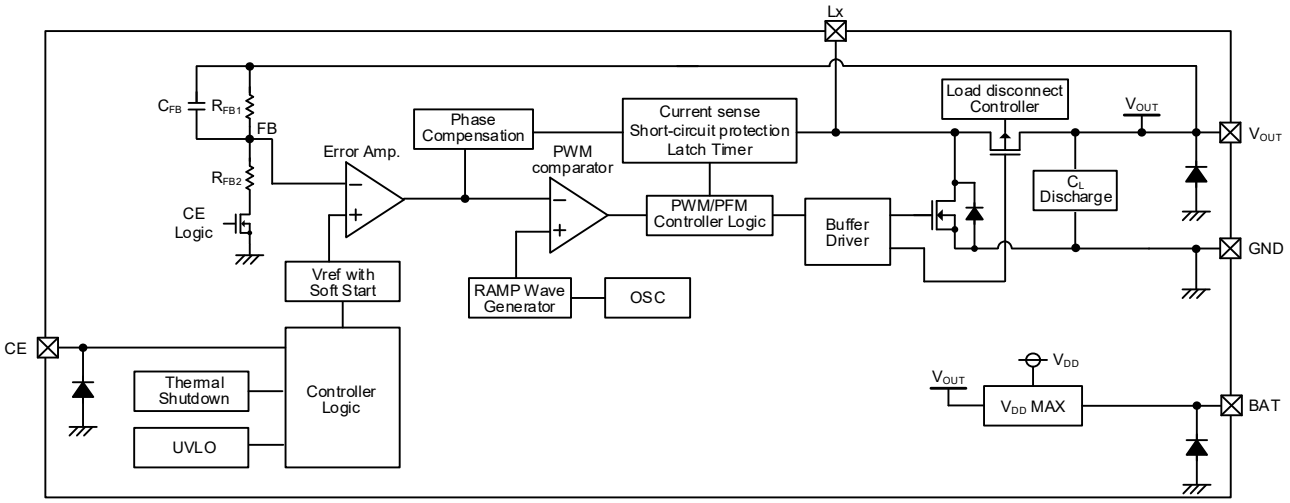
＜Liquid leak reduction: G/J/H/K/M/L types＞

G/H/M/J/K/L types have UVLO function with UVLO release voltage of 1.6V.

This UVLO function stops the IC when the battery voltage drops. This operation reduces battery leakage in 2-cell alkaline battery applications.

■OPERATIONAL EXPLANATION

This IC consists of a reference voltage source, ramp wave circuit, error amplifier, PWM comparator, phase compensation circuit, Nch driver FET, Pch synchronous switching FET and current limiter circuit.



XC9147/XC9148 J types

The main function of this IC is a current mode control step-up DC / DC converter that supports low ESR ceramic capacitors. By adopting current mode control and increasing the oscillation frequency to a high frequency, the size of peripheral parts has been reduced.

The current feedback circuit monitors the Nch driver FET's turn-on current for each switching operation, and modulates the error amplifier output signal to provide multiple feedback signals. This enables a stable feedback loop even when a low ESR capacitor, such as a ceramic capacitor, is used, ensuring stable output voltage.

Regarding to the parts required for operation, select the constants by referring to the part selection section. If a component that is significantly different from this constant is used, proper phase compensation may not be obtained, and DC / DC may operate unstable. Also, when using a capacitance other than a ceramic capacitor, use a low ESR capacitance. If a capacitor with a high ESR is used, heat generation of the capacitor and unstable DC / DC operation may occur.

＜Driver configuration / Load disconnection control (parasitic diode control)＞

A Pch FET is built-in on the High Side and an Nch FET is built-in on the Low Side.

In general Pch FETs, there is a parasitic diode with the source as the cathode and the drain as the anode, but the Pch FETs on the High Side of the XC9147/XC9148 series control the polarity of the parasitic diode.

It is possible to disconnect the load between the input and output sides by controlling this parasitic diode during standby and prevent reverse flow from the output side to the input side when external voltage is applied from the output side.

The control of the polarity of the parasitic diode depends on the types.

＜V_{DD} MAX＞

V_{DD} MAX circuit compares the input voltage and the output voltage then it will select the higher one as the power supply for the IC.

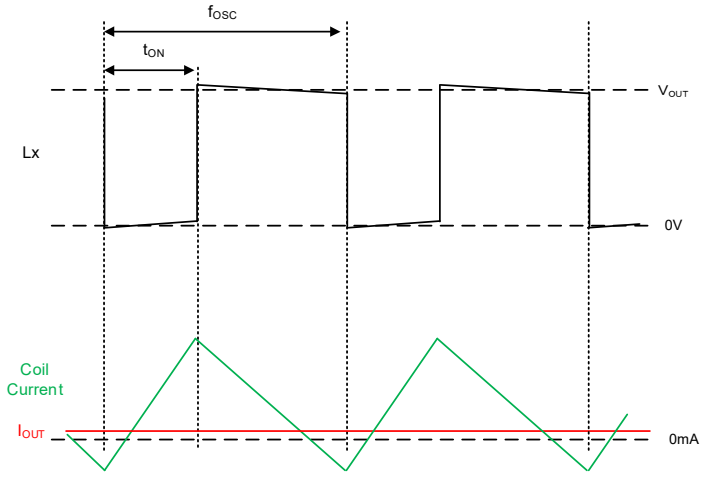
■OPERATIONAL EXPLANATION

＜Normal operation＞

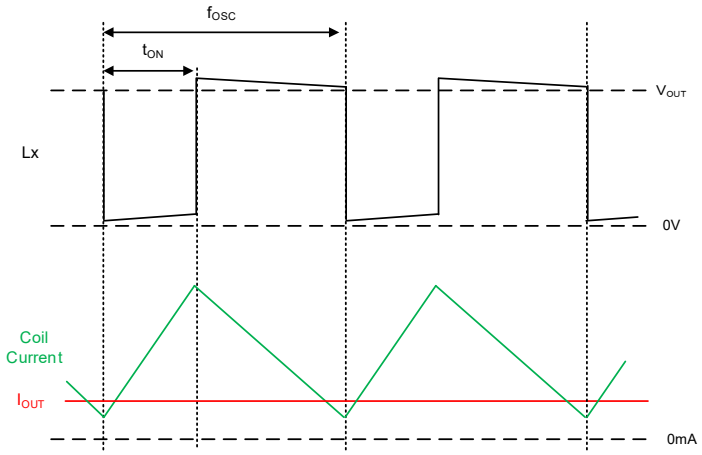
The error amplifier compares the internal reference voltage with FB voltage. In order to input a signal to the PWM comparator, the phase compensation is performed on the resulting error amplifier output. The PWM comparator compares, the signal from the error amplifier with the ramp wave from the ramp wave circuit, and delivers the resulting output to the buffer driver circuit to control the duty during PWM control. The output voltage is stabilized by performing these controls continuously.

XC9147 Series

The XC9147 Series (PWM control) performs switching at a set switching frequency f_{OSC} regardless of the output current. When the V_{OUT} voltage becomes higher than $V_{OUT(T)}$, the V_{OUT} voltage is reduced until the output voltage reaches $V_{OUT(T)}$.



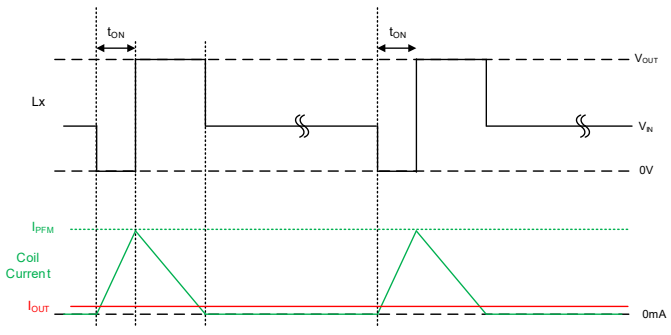
XC9147 Series : Example of light load operation



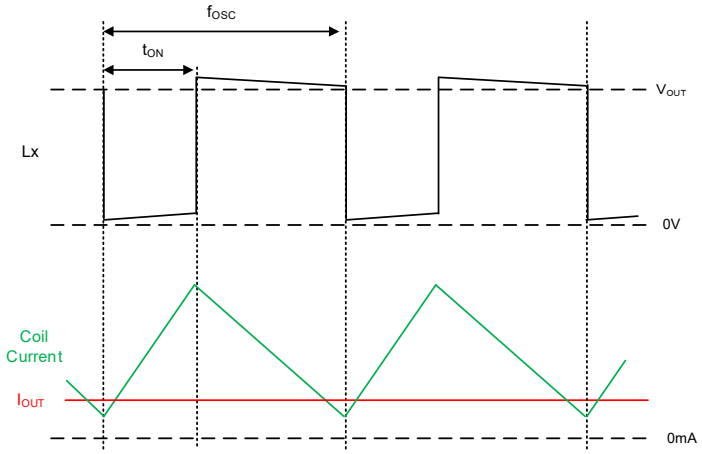
XC9147 Series : Example of heavy load operation

XC9148 Series

The XC9148 Series (PWM/PFM automatic switching control) lowers the switching frequency during light loads by turning on the Low side driver FET when the coil current reaches the PFM current (I_{PFM}). This operation reduces the loss during light loads and achieves high efficiency from light to heavy loads. As the output current increases, the switching frequency increases proportional to the output current, and when the switching frequency increases f_{OSC}, the circuit switches from PFM control to PWM control and the switching frequency becomes fixed.



XC9148 Series: Example of light load operation



XC9148 Series: Example of heavy load operation

■OPERATIONAL EXPLANATION

＜$V_{OUT(T)}$ < V_{BAT} : Input through＞

The behavior of this IC differs depending on the type when an input voltage higher than the set output voltage is applied. The details of operation for each type are as follows.

XC9148 C/F/M/L types: Load Disconnection + No CL Discharge

The XC9148 C/F/M/L types turn off the Pch synchronous switching FET when a voltage higher than the set output voltage is applied to the input voltage, and fix the polarity of the parasitic diode to cathode: V_{OUT}, anode: Lx.

Under this condition, current flows from the input side to the output side via the parasitic diode of the Pch synchronous switching FET, and the output voltage is as follows. When continuously supplying current to the output side via the parasitic diode of the Pch synchronous switching FET, the output current should be 100mA or less.

$V_{OUT(T)} \leqq V_{BAT} \leqq V_{OUT(T)} + VF$: $V_{OUT} \fallingdotseq V_{OUT(T)}$
$V_{OUT(T)} + VF < V_{BAT}$: $V_{OUT} \fallingdotseq V_{BAT} - VF$
* VF : Parasitic diode of Pch synchronous switching FET VF

Except XC9148 C/F/M/L types

For all types except XC9148C/F/M/L, when the input voltage higher than the set output voltage, the Pch synchronous switching FET is turned on.

By this operation, the output voltage will be as follows.

$V_{OUT(T)} \leqq V_{BAT}$: $V_{OUT} \fallingdotseq V_{BAT} - I_{OUT} \times R_{LXP}$ (TYP. 0.2Ω)

■OPERATIONAL EXPLANATION

＜CE function / load disconnection function / bypass mode＞

When a "H" voltage (V_{CEH}) is input to the CE pin, the output voltage is raised by the start-up mode, and then normal operation starts.

When the "L" voltage (V_{CEL}) is input to the CE pin, the IC enters the standby mode, and the current consumption is reduced to the standby current I_{STB}.

The polarity of the parasitic diodes of the Pch synchronous switching FET and Pch synchronous switching FET in the standby mode and the operation of the C_L discharge function depending on the types.

The details of the operation for each type are as follows.

A/D/G/J types : Load disconnection function with C_L discharge function

When the Nch driver FET and Pch synchronous switching FET are turned off, the C_L discharge function operates.

When the C_L discharge function operates, the charge on the output side is quickly discharged and the output voltage is reduced.

When the Nch driver FET and Pch synchronous switching FET are turned off and fix the polarity of the parasitic diode of the Pch synchronous switching FET to anode: V_{OUT} and cathode: Lx, the conduction from the input side to the output side is cut off.

The current consumption during this operation is the standby current I_{STB} (TYP. 0.0μA).

XC9148 C/F/M/L types : Load disconnection function without C_L discharge function

Nch driver FET and Pch synchronous switching FET are turned off.

Even in standby mode, the BAT voltage is compared with the V_{OUT} voltage, and the polarity of the parasitic diode for the Pch synchronous switching FET is controlled so that the input and output sides do not connect through the parasitic diode of the Pch synchronous switching FET.

Even if an external voltage higher than the BAT voltage is applied to the output side by controlling this parasitic diode, the input side and the output side will not connect, and the output OR connection is possible.

The current consumption during this operation is the standby current I_{STB} (TYP. 0.16μA).

XC9148 B/E/H/K types : Bypass mode

When the Nch driver FET turned off and the Pch synchronous switching FET turned on, the resistance between the Lx and V_{OUT} becomes R_{LXP} (TYP. 0.2Ω) and connects.

This operation allows current to be supplied to the output side even in the standby mode, enabling to drive the subsequent devices.

The current consumption during this operation is the standby current I_{STB} (TYP. 0.0μA).

In standby mode (CE="L") Operation list

TYPE	Nch Driver FET / Pch Driver FET	V_{OUT} pin Voltage	C_L Discharge	I_{STB} (TYP.)	Applied Voltage to the V_{OUT} pin (CE="L")
A/D/G/J	OFF /OFF	GND	Active	0.0μA	No (C_L Discharge Operation)
C/F/M/L (Only XC9148)	OFF /OFF	OPEN	-	0.16μA	Yes
B/E/H/K (Only XC9148)	OFF /ON	V_{BAT}	-	0.0μA	No (Reverse Flow toward the input)

■OPERATIONAL EXPLANATION

< Startup Mode / Soft Start >

This function gradually boosting the V_{OUT} voltage up to the set output voltage to suppress the inrush current. The start-up mode is activated when the CE pin is input to "H" and the IC is turned from standby mode to active mode.

The short circuit protection and integral latch functions of the XC9147D/J and XC9148D/E/F/J/K/L types do not operate during the startup mode.

The details of the operation for each type are as follows.

XC9147/XC9148 A/D/G/J types, XC9148 C/F/M/L types : load disconnection function

① $V_{OUT} \leqq V_{BAT}$

The current is supplied to the output side via Pch synchronous switching FET.

Since the Pch synchronous switching FET supplies current to the output side while the current is limited, the V_{OUT} is gradually increased to V_{BAT}.

② $V_{OUT} < V_{OUT(T)} \times 0.9$

After the V_{OUT} voltage reaches to V_{BAT}, the internal reference voltage of the IC is raised slowly.

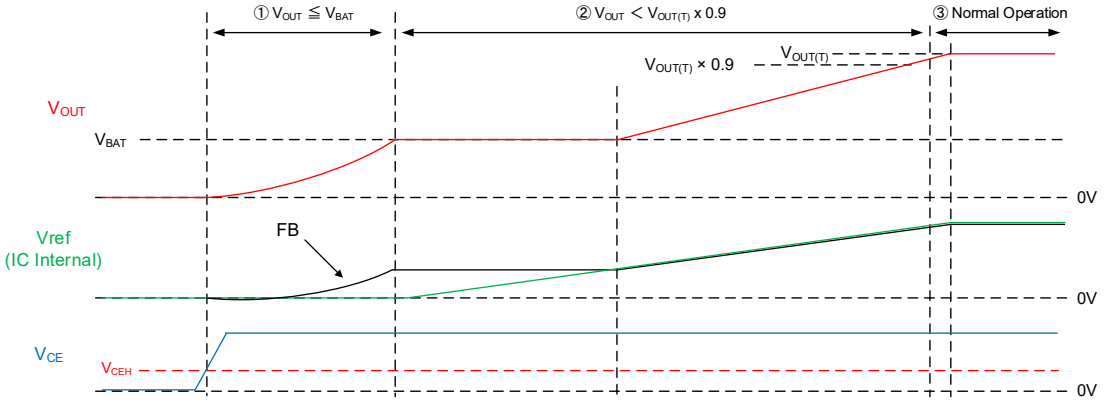
When the FB voltage, which is the voltage divided by the V_{OUT} voltage with R_{FB1} and R_{FB2}, becomes lower than the internal reference voltage of the IC, the switching operation starts.

The slope of the V_{OUT} voltage rise is proportional to the slope of the internal reference voltage of the IC.

③ Normal operation

When the V_{OUT} voltage reaches $V_{OUT(T)} \times 0.9$, the start-up mode is terminated, and the device shifts to normal operation.

However, under the condition of heavy load and large output capacitance, it may not be able to rise to the set output voltage within the start-up period of the reference voltage. In this case, even if the set output voltage is not reached, the IC will shift from start-up mode to normal operation after the completion of the start-up of the reference voltage.



XC9148 B/E/H/K types : Bypass mode

① $V_{OUT} < V_{OUT(T)} \times 0.9$

After becoming active, the internal reference voltage of the IC is raised slowly.

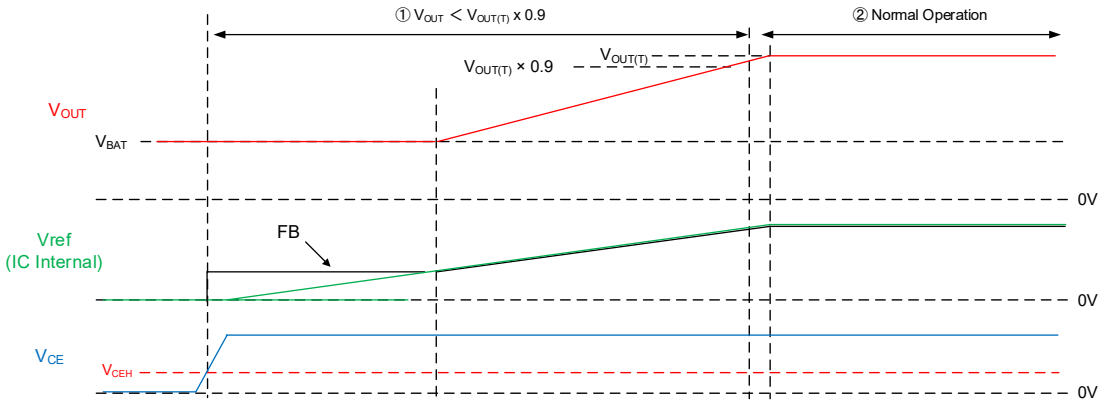
When the FB voltage, which is the voltage divided by the V_{OUT} voltage with R_{FB1} and R_{FB2}, becomes lower than the internal reference voltage of the IC, the switching operation starts, and the output voltage is increased from V_{BAT}.

The slope of the V_{OUT} voltage rise is proportional to the slope of the internal reference voltage of the IC.

② Normal operation

When the V_{OUT} voltage reaches $V_{OUT(T)} \times 0.9$, the start-up mode is terminated, and the device shifts to normal operation.

However, under the condition of heavy load and large output capacitance, it may not be able to rise to the set output voltage within the start-up period of the reference voltage. In this case, even if the set output voltage is not reached, the IC will shift from start-up mode to normal operation after the completion of the start-up of the reference voltage.



■OPERATIONAL EXPLANATION

＜Current Limit / Short Circuit Protection / Integral Latch＞

The current limit function of this IC monitors the current flowing in the Nch driver (=coil current) for each switching cycle, and when the current flowing through the Nch driver FET reached the current limit value I_{LIM} (TYP. 2.42A @ $V_{OUT(T)}$=5.0V), it will be in the overcurrent detection state.

When the overcurrent detection state occurs, the Nch driver FET is turned off and the detection state is maintained during this switching cycle. If the current flowing to the Nch driver FET is less than the current limit value I_{LIM} in the next switching cycle, the overcurrent detection state is released.

If the overcurrent detection state is continued or if there is a significant drop in output voltage, the short circuit protection function and integral latch function are activated depending on the type.

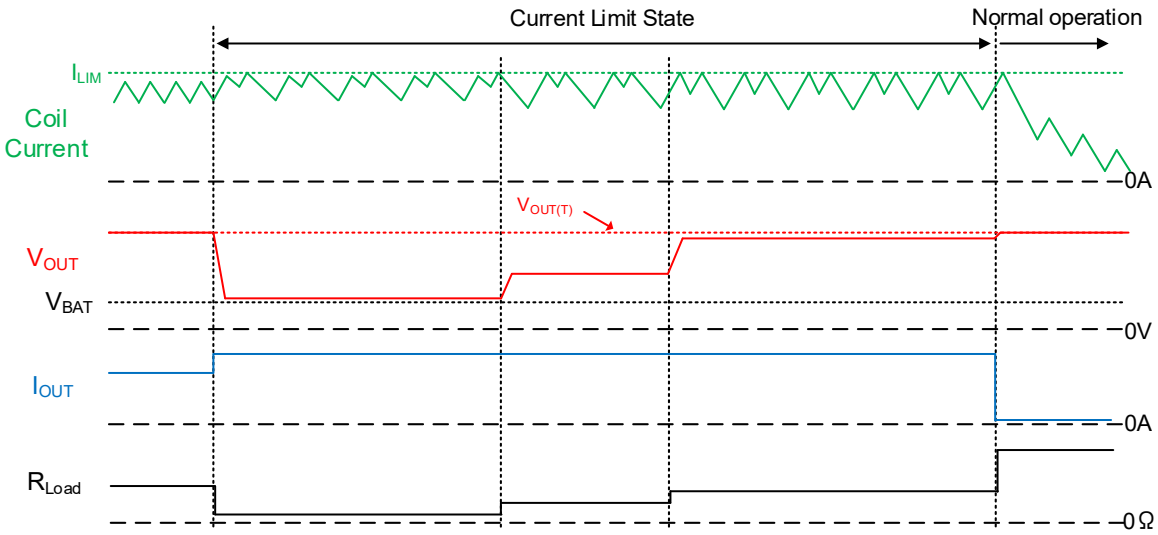
The details of the operation for each type are as follows.

No short circuit protection/integral latch: XC9147 A/G types ,XC9148 A/B/C/G/H/M types

① If the current flowing in the Nch driver FET reaches the current limit value I_{LIM}, it will be in the overcurrent detection state. The Nch driver FET turns off and remains off during this switching cycle.

②In the next switching cycle, the Nch driver FET turns on.
If the overcurrent state continues and the current flowing to the Nch driver FET reaches the current limit value I_{LIM}, the overcurrent detection state is maintained.

③ If overcurrent state continues, ① and ② are repeated.



＜Current Limit / Short Circuit Protection / Integral Latch (Continued)＞

Short circuit protection/with integral latch : XC9147 D/J types, XC9148 D/E/F/J/K/L types

In the XC9147D/J and XC9148D/E/F/J/K/L types, if the overcurrent detection state continues and the output voltage drops significantly, the driver FETs are turned off and latch stopped by the operations shown in (a) and (b).

Case (a) : When the overcurrent detection status is maintained

① When the current flowing to the Nch driver FET reaches the current limit value I_{LIM}, the overcurrent detection state occurs. The Nch driver FET is turned off and kept off during this switching cycle.
When the XC9147 D/J and XC9148 D/E/F/J/K/L types become to the overcurrent detection status, the integral latch timer starts counting.

② In the next switching cycle, the Nch driver FET turns on.
If the over-current state continues and the current flowing to Nch driver FET reaches the current limit I_{LIM}, the over current detection state is maintained.

③ When the overcurrent detection state is maintained and the integral latch timer continues to count t_{LAT} (TYP. 1.2MHz: 200μs, 3.0MHz: 100μs), the Nch driver FET and Pch synchronous switching FET are turned off and the integral latch function latches. However, for XC9147D type and XC9148D/E/F types, the integral latch function does not operate when the input voltage is less than the latch release voltage V_{LAT_R}(TYP. 1.2V).

Case (b) : When the output voltage drops significantly

① When the current flowing to Nch driver FET reaches the current limit value I_{LIM}, the overcurrent detection state occurs. The Nch driver FET is turned off and kept off during this switching cycle.

② In the next switching cycle, the Nch driver FET turns on.
If the over-current state continues and the current flowing to Nch driver FET reaches the current limit I_{LIM}, the over-current detection state is maintained.

③ If the output voltage becomes equal or less than the short circuit protection threshold voltage V_{SHORT}(TYP. V_{BAT}) during the over current detection state, the Nch driver FET and Pch synchronous switching FET are turned off and the short circuit protection function operates and latches.
However, for XC9147D type and XC9148D/E/F types, the short circuit protection function does not operate when the input voltage is equal to or less than the latch release voltage V_{LAT_R}(TYP. 1.2V).

■Conditions for recovery from latch stop

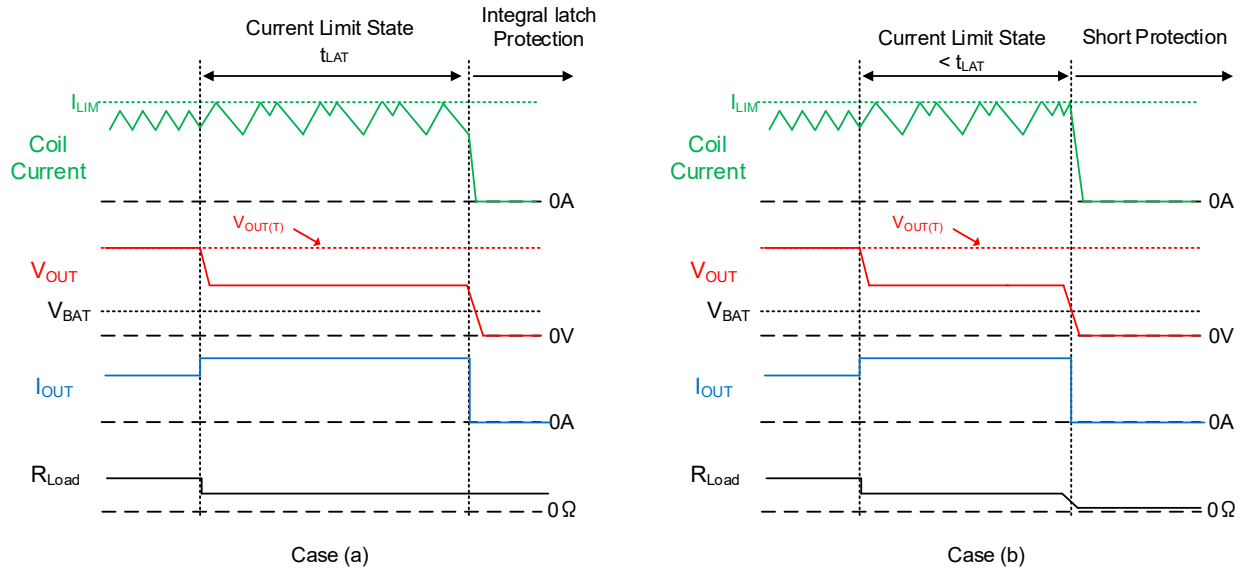
There are two conditions for recovery from latch stop by the current limited integral latch timer and short circuit protection. In addition, the recovery from the latch stop raises the output voltage via the start-up mode and shifts to normal operation.

Without UVLO function : XC9147 D type, XC9148 D/E/F types

- Input the "L" voltage to the CE pin to put it in the standby mode and then put it in the active mode.
- Set the input voltage V_{BAT} below the latch release voltage V_{LAT_R}(TYP. 1.2V).

With UVLO function : XC9147 J type, XC9148 J/K/L types

- Input the "L" voltage to the CE pin to put it in the standby mode and then put it in the active mode.
- After setting the input voltage to V_{UVLO_R}-V_{UVLO_HYS} or less and setting the UVLO detection state, apply the voltage above V_{UVLO_R} to the normal state.



■OPERATIONAL EXPLANATION

＜Thermal shutdown＞

The junction temperature is monitored to protect the IC from thermal destruction.

When the junction temperature reaches the thermal shutdown detection temperature T_{TSD} (TYP. 150°C), the thermal shutdown activated, and the Nch driver FET and Pch synchronous switching FET are turned off, and the output voltage drops. When the chip temperature drops to the thermal shutdown release temperature T_{TSD}-T_{HYS} (TYP. 125°C) by stopping the current supply, the output voltage is turned on by the start-up mode, and then normal operation starts.

In order to suppress the current consumption at the light load, XC9148 series stops the thermal shutdown function when the output current is small at the PFM control.

＜UVLO＞

XC9147 G/J types and XC9148 G/H/M/J/K/L types have UVLO function.

If BAT voltage becomes equal or less than V_{UVLO_R} (TYP.1.60V)- V_{UVLO_HYS} (TYP.0.15V), UVLO Detect Delay: t_{DF} (TYP. 1.2MHz: 200µs, 3.0MHz: 100µs) continues, then UVLO becomes active.

When UVLO detection state is reached, the switching operation is stopped and Nch driver FET and Pch synchronous switching FET are turned off.

If BAT voltage is higher than V_{UVLO_R}, the output voltage is raised by the start-up mode, and then normal operation is performed.

The consumption current of the products with UVLO function is slightly higher than the products without UVLO function due to the operation of UVLO function

＜C_L Discharge＞

A/D/G/J types can discharge the electric charge at the output capacitor (C_L) quickly during standby mode(CE="L") via the Nch FET located between V_{OUT} and GND.

Electric charge at the output capacitor (C_L) is quickly discharged so that it may avoid application malfunction during standby mode.

Discharge time of the output capacitor (C_L) is set by the C_L discharge resistance (R_{DCHG}) and the output capacitor (C_L). By setting time constant of a C_L discharge resistance value [R_{DCHG}] and an output capacitor value (C_L) as τ ($\tau = C_L \times R_{DCHG}$), discharge time can be the calculated by the following formulas.

However, the C_L discharge resistance [R_{DCHG}] is depends on the V_{BAT} or V_{OUT}. We recommend that you fully check actual performance.

$$V = V_{OUT(T)} \times e^{-t/\tau}$$
$$t = \tau \times \ln (V_{OUT(T)} / V)$$

V	: Output voltage after discharge
$V_{OUT(T)}$	: Target voltage
t	: Discharge time
τ	: $C_L \times R_{DCHG}$
C_L	: Capacitance of Output capacitor (C_L)
R_{DCHG}	: C_L Discharge resistance, it depends on the V_{BAT} or V_{OUT}

■NOTES ON USE

1) For the phenomenon of temporal and transitional voltage decrease or voltage increase, the IC may be damaged or deteriorated if IC is used beyond the absolute MAX. specifications. Also, if used under out of the recommended operating range, the IC may not operate normally or may cause deterioration.

2) Spike noise and ripple voltage arise in a switching regulator as with a DC/DC converter. These are greatly influenced by external component selection, such as the coil inductance, capacitance values, and board layout of external components. Once the design has been completed, verification with actual components should be done.

3) The DC/DC converter performance is greatly influenced by not only the ICs' characteristics, but also by those of the external components. Care must be taken when selecting the external components. Especially for CL load capacitor, it is recommended to use type B capacitors(JIS regulation) or X7R, X5R capacitors (EIA regulation).

4) When the CE pin is open, the IC will operate indefinitely. Therefore, the CE pin should not be open and should be set to a fixed voltage. To prevent the IC and peripheral devices from malfunctioning due to pin-to-pin shorts, or to prevent the IC from being damaged by external noise, etc., it is recommended that a resistor of 1MΩ or less be connected to the CE pin instead of connecting it directly to the V_{BAT}.

5) When the boost ratio is small, PWM control oscillates intermittently.
This may cause the switching frequency to drop below f_{OSC} or increase output voltage ripple.
To suppress the ripple voltage, increase the capacitance value of the output capacitor and take measures

6) When connecting an external power supply to the output side, please use the XC9148 C/F/M/ L types.
When using the XC9148C/F/M/L type exclusion, depending on the bias conditions, the IC may break down and reverse flow to the input side may occur.

7) Depending on the detection delay time of the current limit circuit, a coil current exceeding the limit current value I_{LIM} may flow.

8) Under the following conditions, the current limit function may not operate.
XC9147 D/J types, XC9148 D/E/F/J/K/L types are used the integral latch method. In this case, the integral latch of the current limit function and the latch stop by the short circuit protection function do not operate in these types

<u>The boost ratio is small</u>
When the boost ratio is small, the required duty is low and the on-time of the Nch driver FET on the low side is short.
If this on-time is shorter than the detection delay of the current limit circuit, the current limit function may not operate.

<u>The boost ratio is high</u>
When the boost ratio is high, the coil current may be limited below the current limit value due to the maximum duty ratio, on-resistance, and DCR of the coil, and the current limit function may not operate.

9) The current limit function is a function that limits the current flowing through the Nch driver FET, and does not limit the current flowing through the Pch synchronous switching FET.
Therefore, an overcurrent may flow in the parasitic diode of the Pch synchronous switching FET and the Pch synchronous switching FET, and the IC may be destroyed.

10) XC9147 D/J types, XC9148 D/E/F/J/K/L types have short-circuit protection and integral latch function. If the output voltage drops sharply due to an output short circuit, etc. The internal power supply of the IC may drop sharply by the circuit delay of the V_{DD} MAX circuit. As a result, the latch state of the short-circuit protection function may be reset and the latch stop may not be maintained.

■NOTES ON USE

11) If a large capacitor is used for the output capacitance or if a heavy load is pulled during startup mode, the follow operations may occur.

With short circuit protection/integral latch : XC9147 D/J types, XC9148 D/E/F/J/K/L types

For the products with integral latch, after the start-up mode is completed, the integral latch function may not operate, and the output voltage may not rise to the set output voltage due to the continuation of the current limit function.

Without short circuit protection/integral latch : XC9147 A/G types, XC9148 A/B/C/G/H/M types

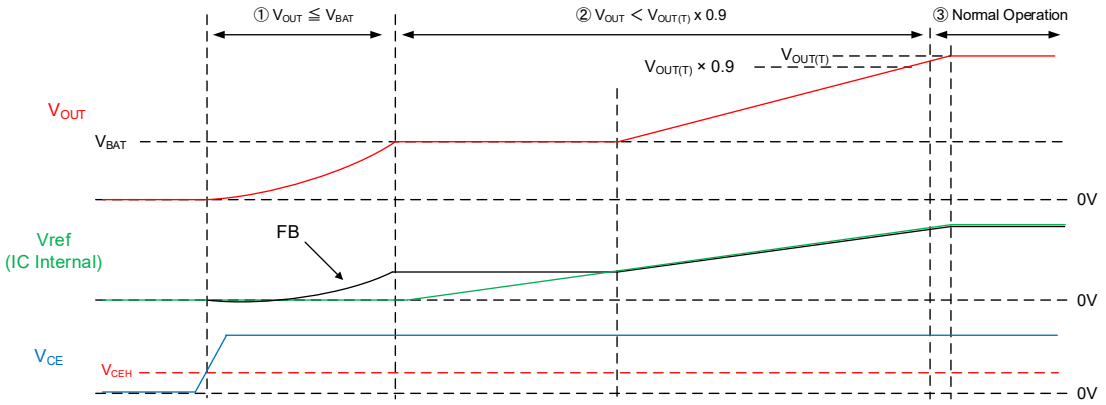
The output voltage may not rise to the set output voltage during start-up mode.
After the start-up mode is completed, the output voltage rises up to the set output voltage while the current limit function is operating, so overshooting may occur in the output voltage.

12) When the input voltage is higher than the set output voltage, the XC9148C/F/M/L types turn off the Pch synchronous switching FET and fix the parasitic diode polarity to cathode: V_{OUT} and anode: Lx, when a voltage higher than the set output voltage is applied to the input voltage.

Under these conditions, when the output current is applied, the current flows through the parasitic diode of the Pch synchronous switching FET.
Continuously applying an output current of 100mA or more or momentarily applying excessive output current may cause IC deterioration.

If the input voltage is higher than the set output voltage, or if you want the output current to input more than 100mA continuously, we recommend using the types of XC9148C/F/M/L exclusion.

13) The XC9148 C/F/M/L types fix the parasitic diode polarity of the Pch synchronous switching FET to cathode: V_{OUT} and anode: Lx during the period of " $V_{OUT} < V_{OUT(T)} \times 0.9$" in the startup mode.
If a current of 100mA or more is applied to the parasitic diode of the Pch synchronous switching FET during this period, the output voltage may not rise to the set output voltage.
When the XC9148 C/F/M/L types are operate in the start-up mode, do not apply output current until the output voltage becomes higher than the input voltage and the switching operation starts.



14) Torex places an importance on improving our products and their reliability. We request that users incorporate fail safe designs and post aging protection treatment when using Torex products in their systems.

■NOTES ON USE

●Instructions of pattern layouts.

Especially noted in the pattern layout are as follows.
Please refer to the reference pattern layout on the next page.

(a) Wire the large current line using thick, short connecting traces.
This makes it possible to reduce the wire impedance, which is expected to reduce noise and improve heat dissipation.
If the wire impedance of the large current line is large, it may cause noise or the IC to not operate normally.
Especially when the noise is large, the current limit function and the integral latch function may not work.

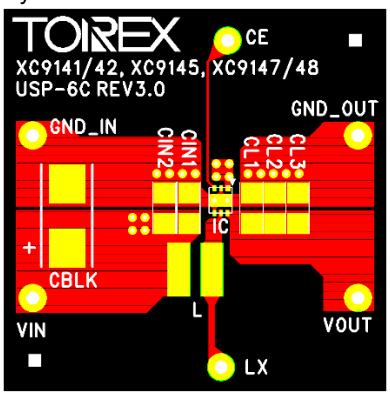
(b) Place the input capacitance C_{IN}, output capacitance C_L, inductor L and IC which the large current flows on the same surface. If they are placed on both sides, a large current will flow through Via, which has high impedance, it may cause noise and the IC may not operate normally.

(c) Please mount each external component as close to the IC as possible.
Especially place the output capacitance C_L near the IC and connect it with as low impedance as possible.
If the output capacity C_L and IC are too far apart, it may cause noise or the IC may not operate normally.

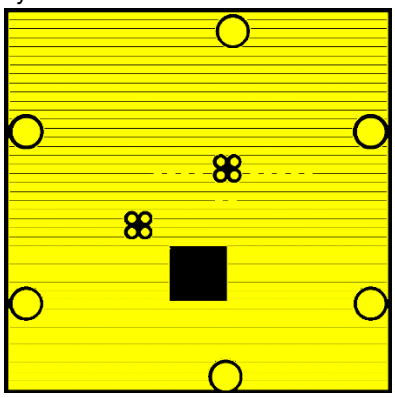
<Pattern layout>

USP-6C

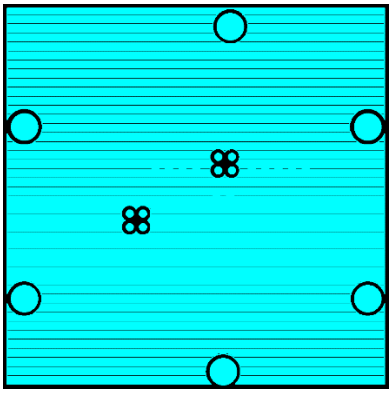
Layer 1



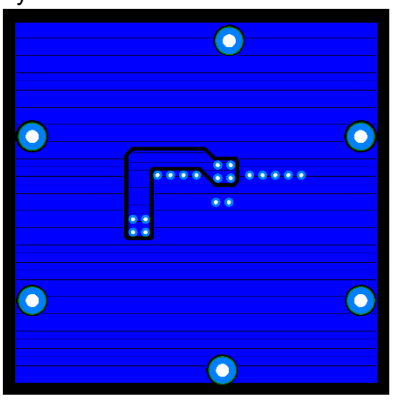
Layer 2



Layer 3

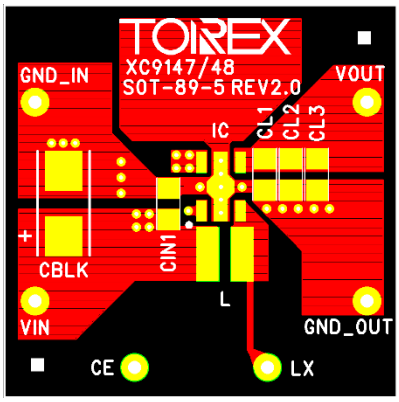


Layer 4

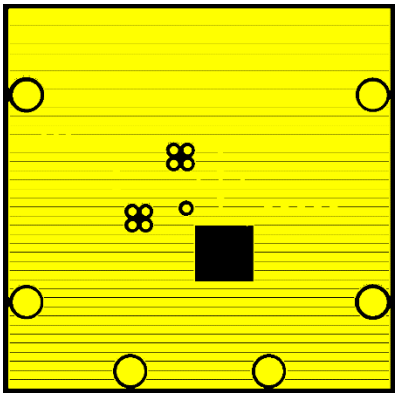


SOT-89-5

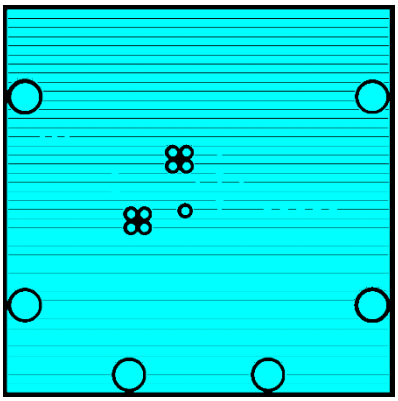
Layer 1



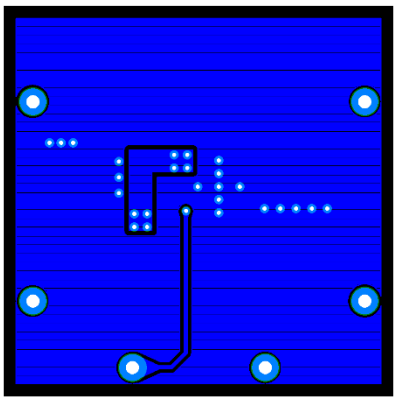
Layer 2



Layer 3



Layer 4

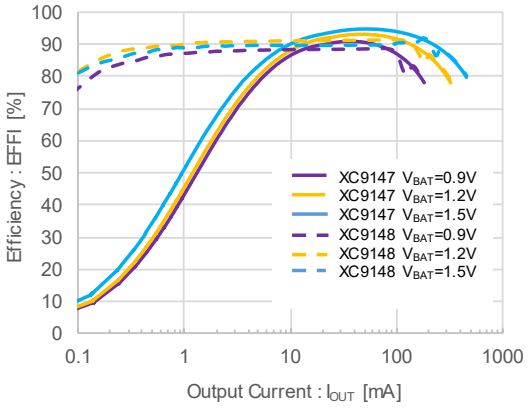


■TYPICAL PERFORMANCE CHARACTERISTICS

(1) Efficiency vs. Output Current

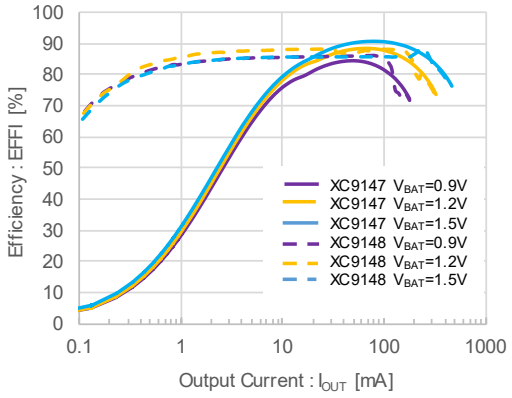
$V_{OUT(T)}$=1.8V, f_{OSC}=1.2MHz

L = 4.7μH(XGL3530-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x3)



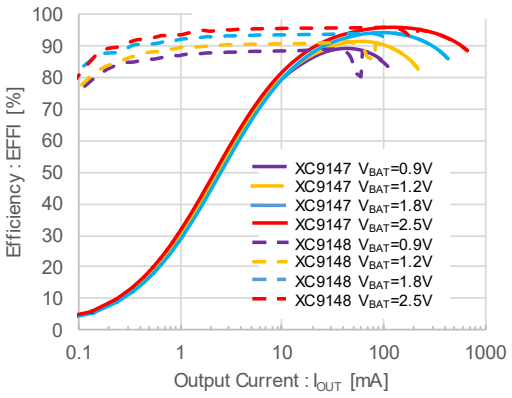
$V_{OUT(T)}$=1.8V, f_{OSC}=3.0MHz

L = 2.2μH(XGL3520-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x2)



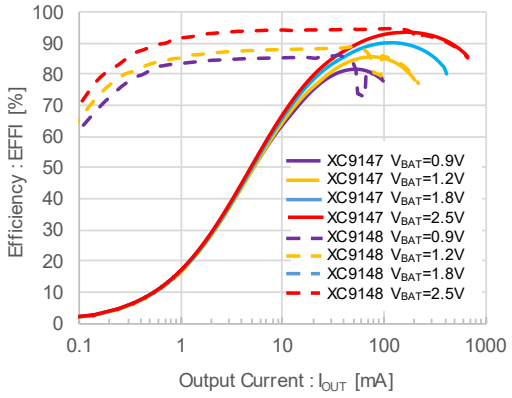
$V_{OUT(T)}$=3.3V, f_{OSC}=1.2MHz

L = 4.7μH(XGL3530-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x3)



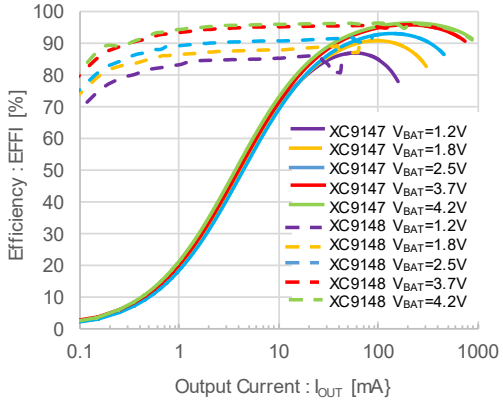
$V_{OUT(T)}$=3.3V, f_{OSC}=3.0MHz

L = 2.2μH(XGL3520-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x2)



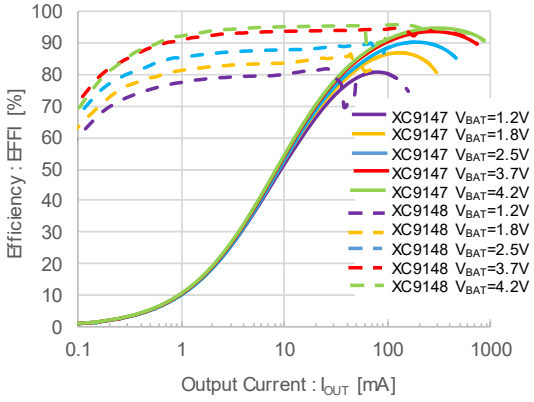
$V_{OUT(T)}$=5.0V, f_{OSC}=1.2MHz

L = 4.7μH(XGL3530-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x3)



$V_{OUT(T)}$=5.0V, f_{OSC}=3.0MHz

L = 2.2μH(XGL3520-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x2)

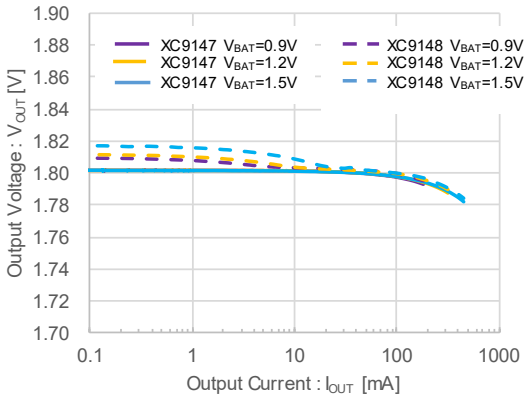


■TYPICAL PERFORMANCE CHARACTERISTICS

(2) Output Voltage vs. Output Current

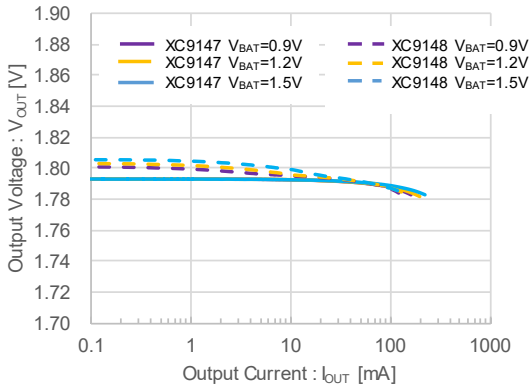
$V_{OUT(T)}$=1.8V, f_{OSC}=1.2MHz

L = 4.7μH(XGL3530-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x3)



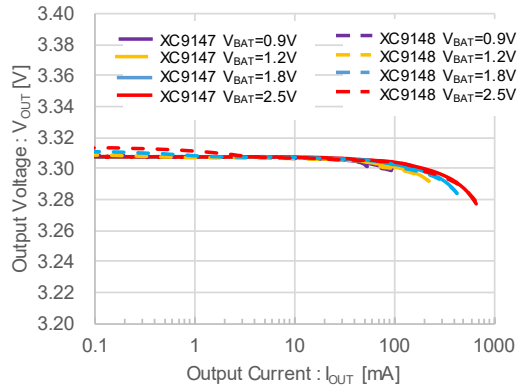
$V_{OUT(T)}$=1.8V, f_{OSC}=3.0MHz

L = 2.2μH(XGL3520-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x2)



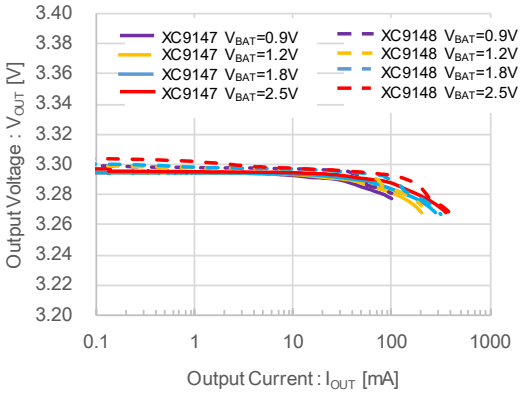
$V_{OUT(T)}$=3.3V, f_{OSC}=1.2MHz

L = 4.7μH(XGL3530-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x3)



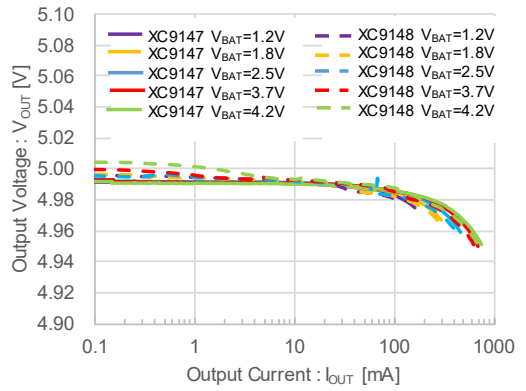
$V_{OUT(T)}$=3.3V, f_{OSC}=3.0MHz

L = 2.2μH(XGL3520-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x2)



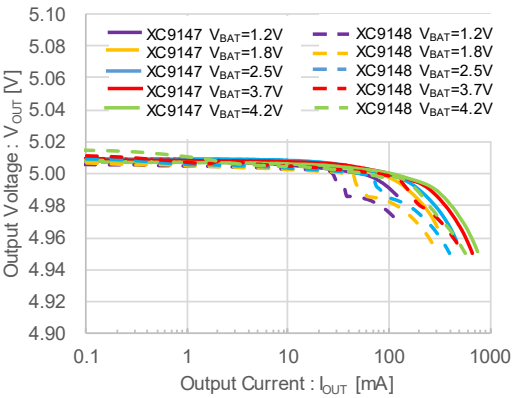
$V_{OUT(T)}$=5.0V, f_{OSC}=1.2MHz

L = 4.7μH(XGL3530-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x3)



$V_{OUT(T)}$=5.0V, f_{OSC}=3.0MHz

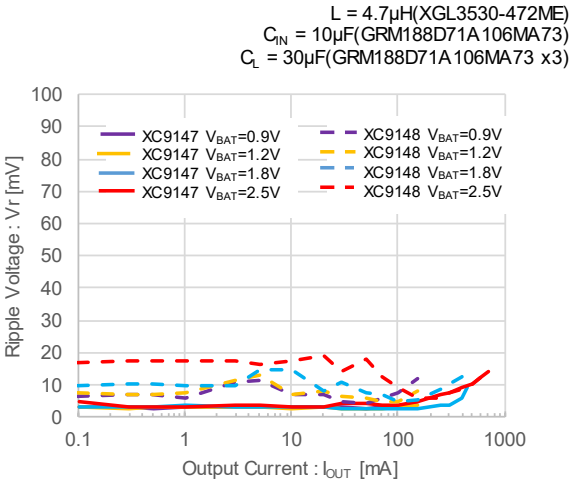
L = 2.2μH(XGL3520-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x2)



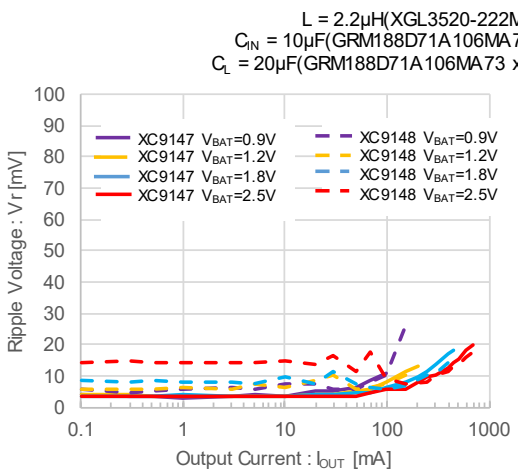
■TYPICAL PERFORMANCE CHARACTERISTICS

(3) Ripple Voltage vs. Output Current

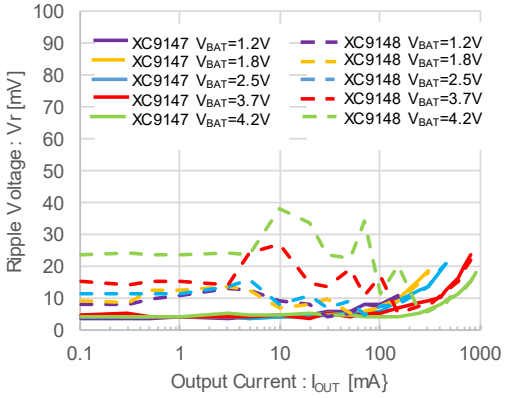
$V_{OUT(T)}$=3.3V, f_{OSC}=1.2MHz



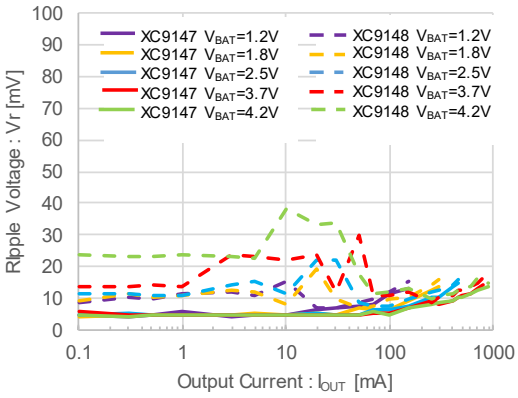
$V_{OUT(T)}$=3.3V, f_{OSC}=3.0MHz



$V_{OUT(T)}$=5.0V, f_{OSC}=1.2MHz



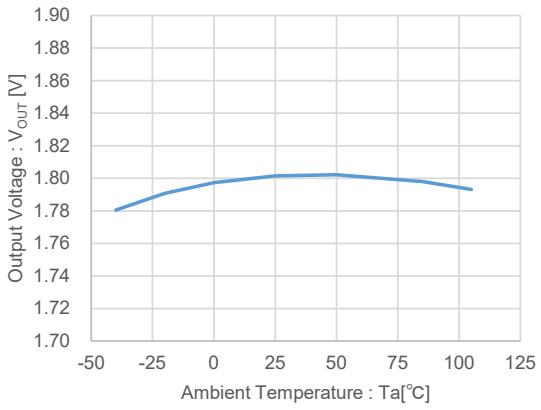
$V_{OUT(T)}$=5.0V, f_{OSC}=3.0MHz



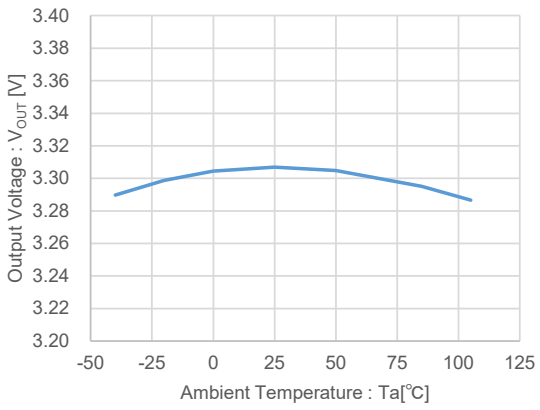
■TYPICAL PERFORMANCE CHARACTERISTICS

(4) Output Voltage vs. Ambient Temperature

$V_{OUT(T)}$=1.8V

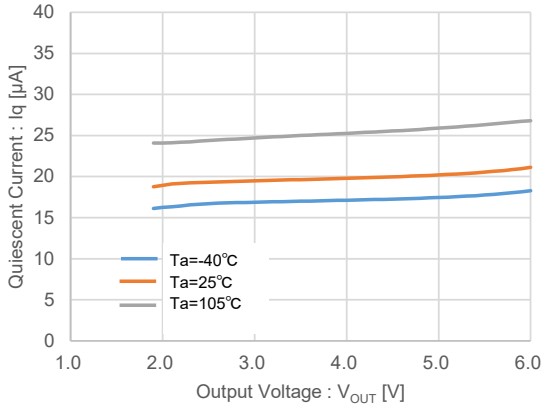


$V_{OUT(T)}$=3.3V

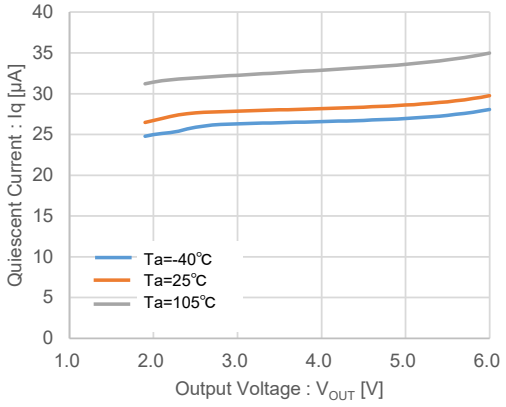


(5) Quiescent Current vs. Output Voltage

$V_{OUT(T)}$=1.8V, f_{OSC}=1.2MHz



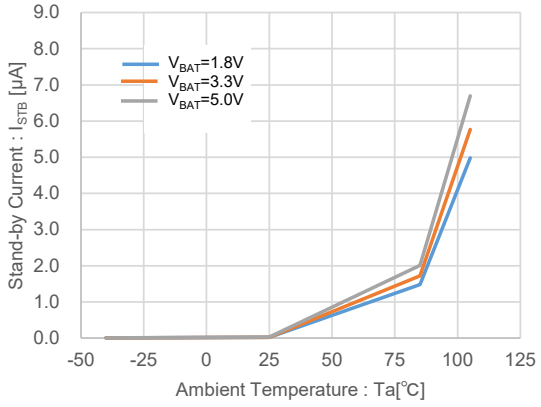
$V_{OUT(T)}$=1.8V, f_{OSC}=3.0MHz



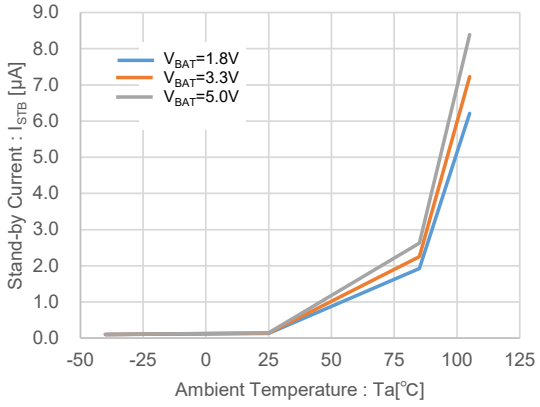
■TYPICAL PERFORMANCE CHARACTERISTICS

(6) Stand-by Current vs. Ambient Temperature

A/B/D/E/G/H/J/K Type

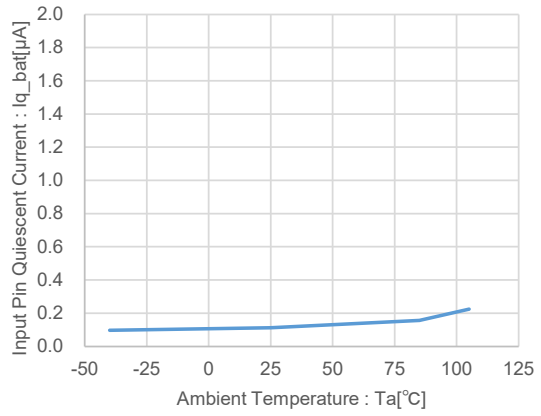


C/F/M/L Type

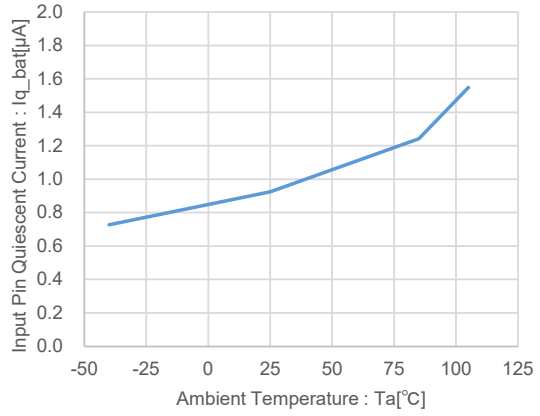


(7) Input Pin Qulescent Current vs. Ambient Teperature

XC9148C/F Type, $V_{OUT(T)}$=3.6V

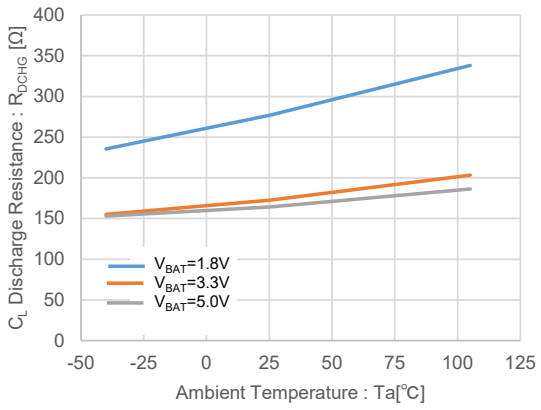


XC9148M/L Type, $V_{OUT(T)}$=3.6V



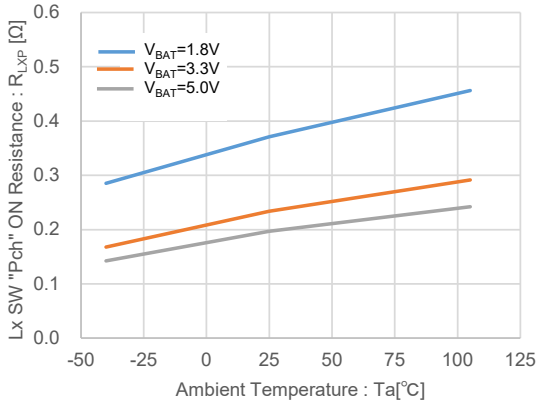
(8) C_L Discharge Resistance vs. Ambient Teperature

A/D/G/J Type

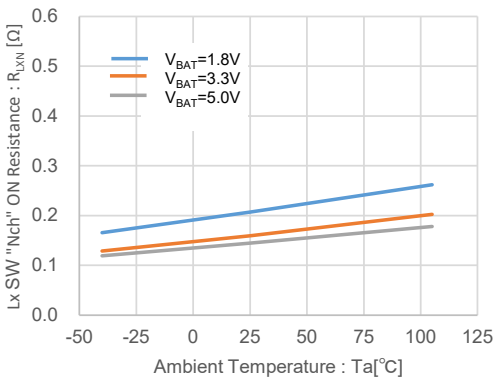


■TYPICAL PERFORMANCE CHARACTERISTICS

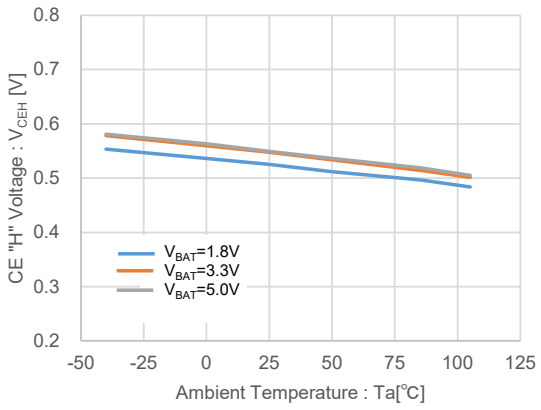
(9) Lx SW "Pch" ON Resistance vs. Ambient Temperature



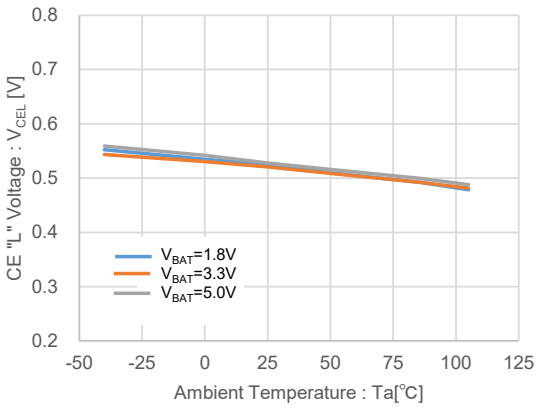
(10) Lx SW "Nch" ON Resistance vs. Output Voltage



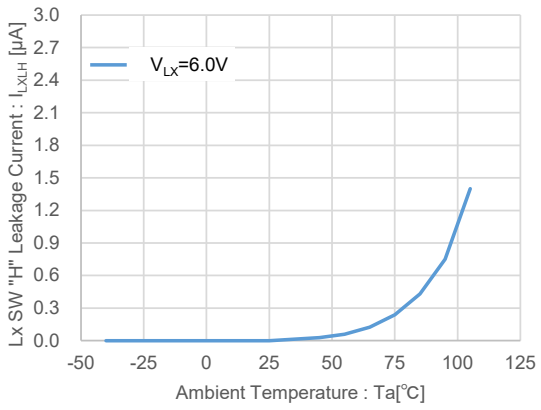
(11) CE "H" Voltage vs. Ambient Temperature



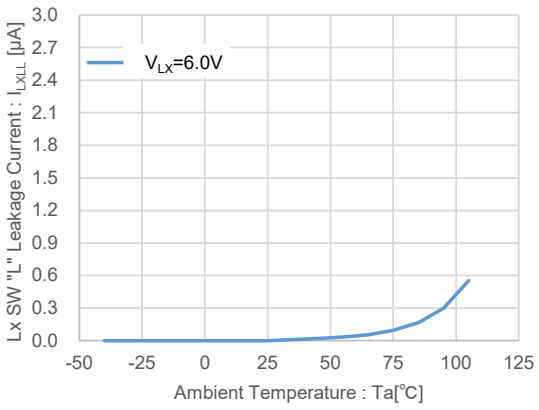
(12) CE "L" Voltage vs. Ambient Temperature



(13) Lx SW "H" Leakage Current vs. Ambient temperture



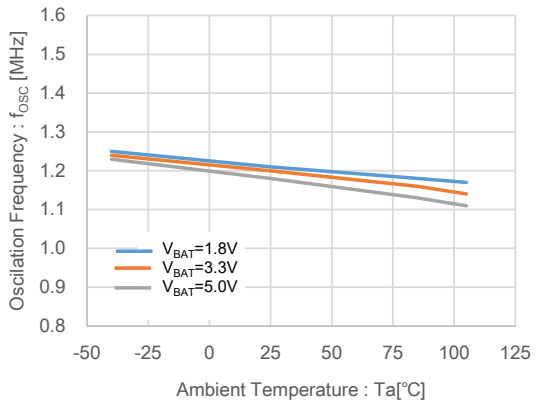
(14) Lx SW "L" Leakage Current vs. Ambient temperture



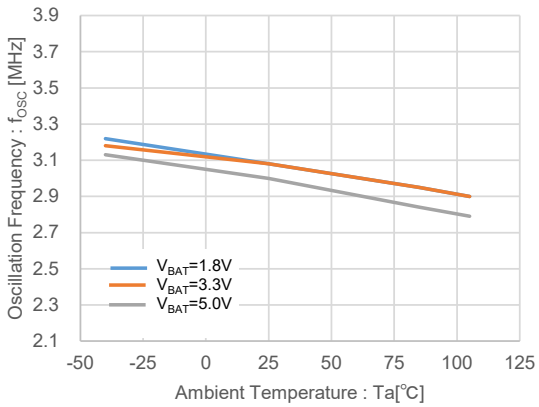
■TYPICAL PERFORMANCE CHARACTERISTICS

(15) Oscillation Frequency vs. Ambient temperture

f_{osc}=1.2MHz

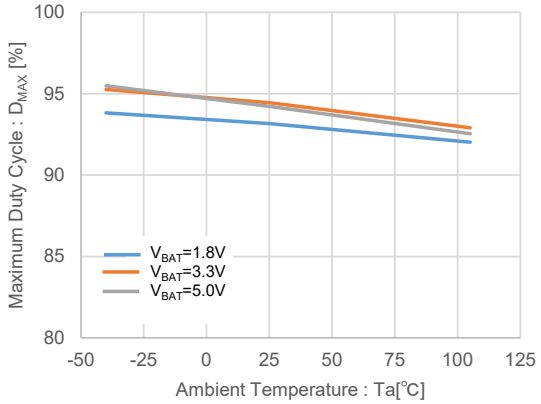


f_{osc}=3.0MHz

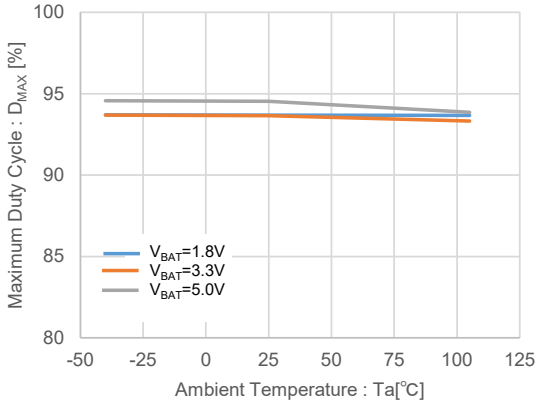


(16) Maximum Duty Cycle vs. Ambient temperture

f_{osc}=1.2MHz

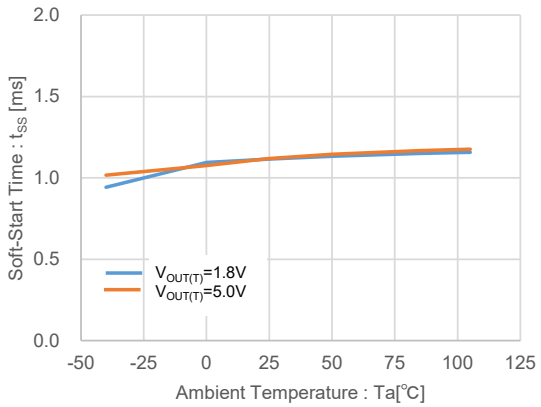


f_{osc}=3.0MHz

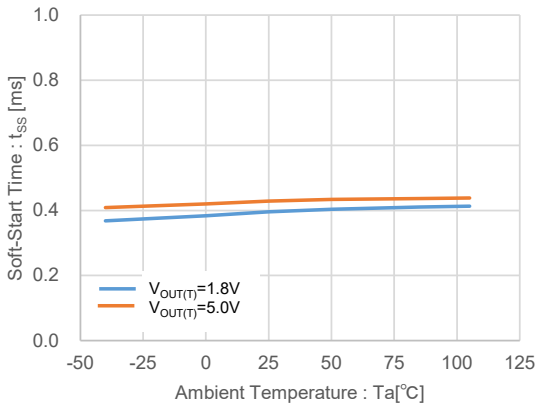


(17) Soft-Start Time vs. Ambient temperature

f_{osc}=1.2MHz



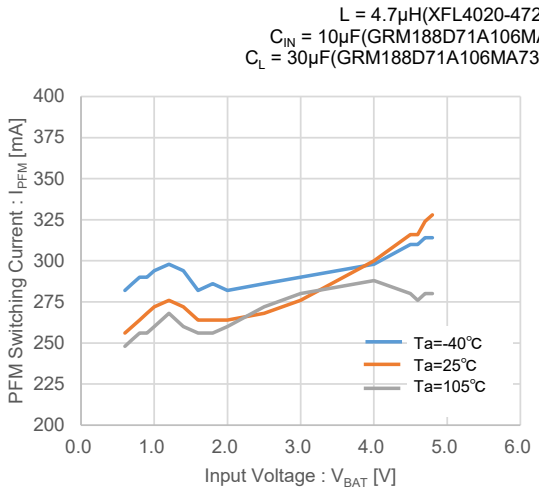
f_{osc}=3.0MHz



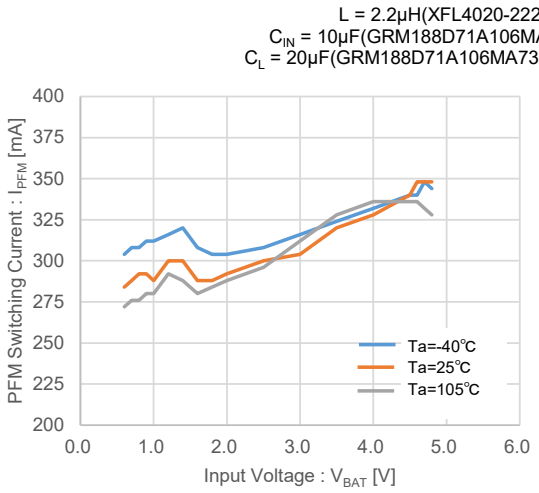
■TYPICAL PERFORMANCE CHARACTERISTICS

(18) PFM Switching Current vs. Input Voltage

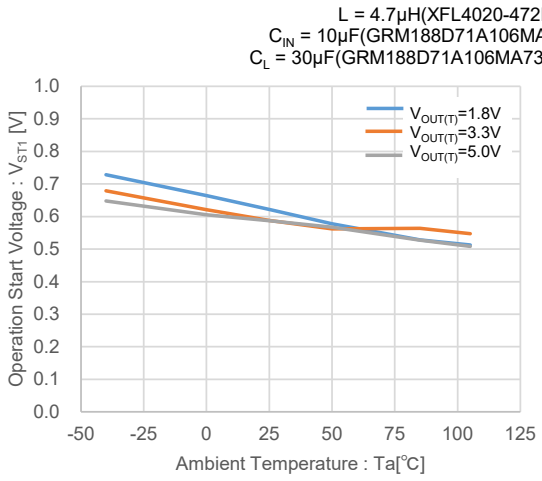
XC9148x50C ($V_{OUT(T)}$=5.0V, f_{OSC}=1.2MHz)



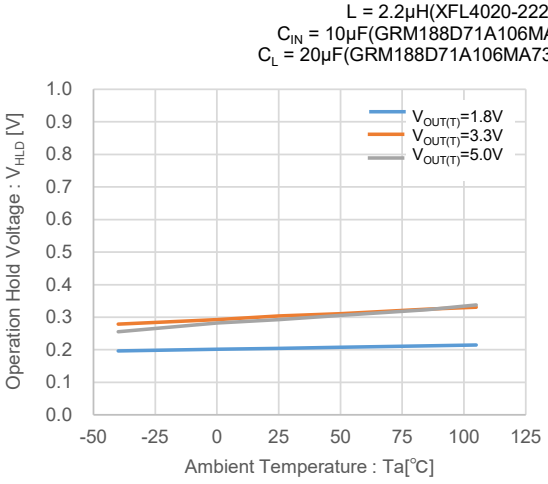
XC9148x50D ($V_{OUT(T)}$=5.0V, f_{OSC}=3.0MHz)



(19) Operation Start Voltage vs. Ambient temperture

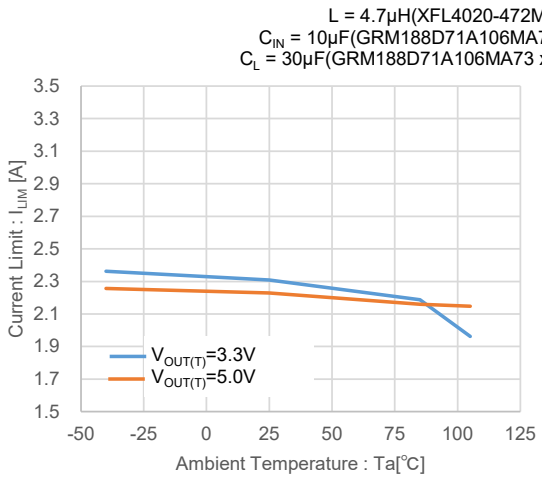


(20) Operation Hold Voltage vs. Ambient temperture

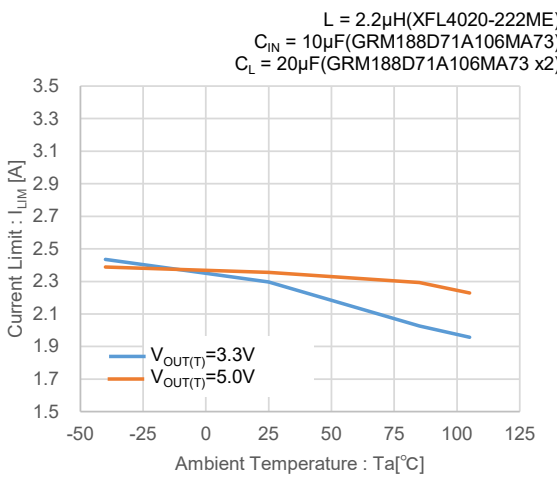


(21) Current Limit vs. Ambient temperture

f_{OSC}=1.2MHz



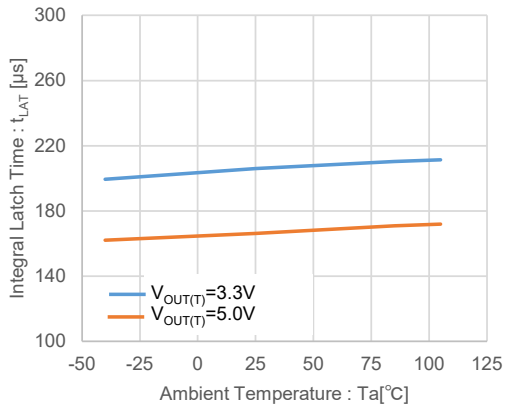
f_{OSC}=3.0MHz



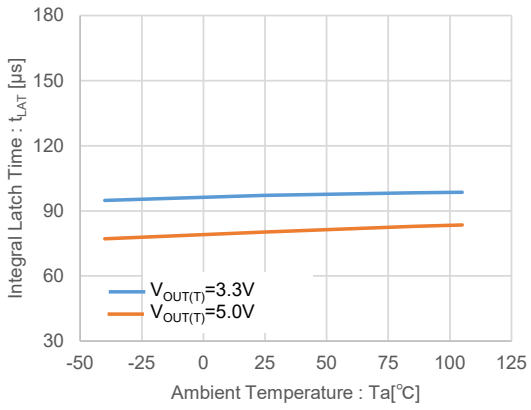
■TYPICAL PERFORMANCE CHARACTERISTICS

(22) Integral Latch Time vs. Ambient temperture

D/E/F/J/K/L Type, f_{osc}=1.2MHz

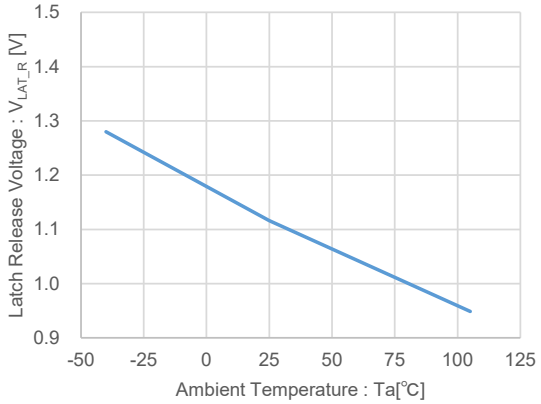


D/E/F/J/K/L Type, f_{osc}=3.0MHz



(23) Latch Release Voltage vs. Ambient temperture

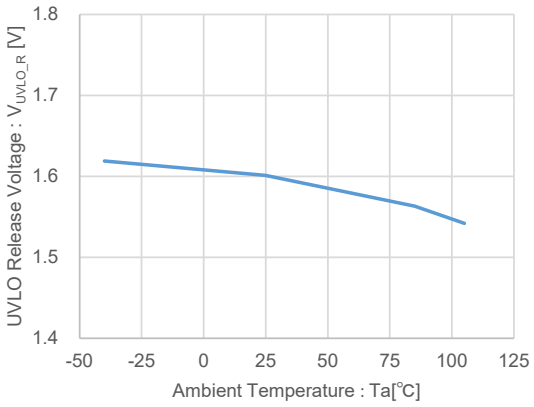
D/E/F/J/K/L Type



■TYPICAL PERFORMANCE CHARACTERISTICS

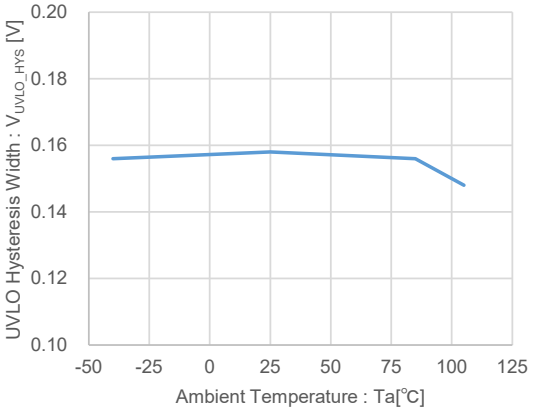
(24) UVLO Release Voltage vs. Ambient Temperature

G/H/M/J/K/L Type



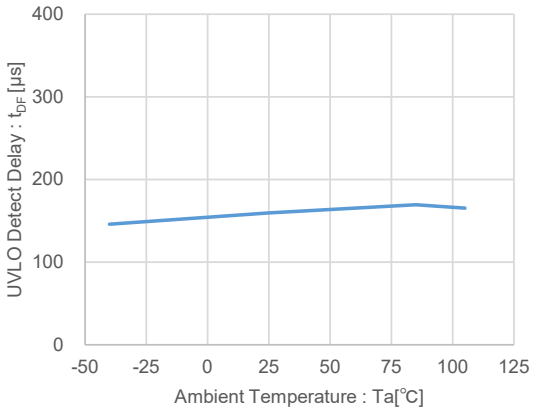
(25) UVLO Hysteresis Voltage vs. Ambient Temperature

G/H/M/J/K/L Type

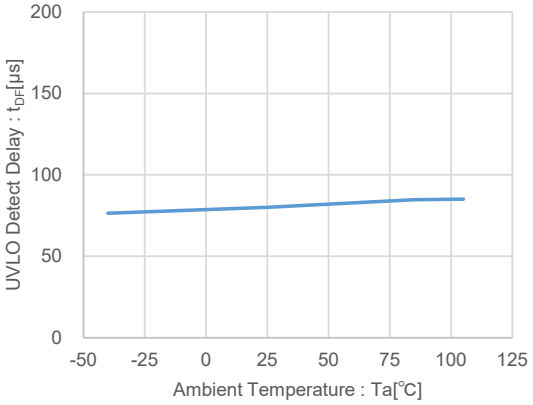


(26) UVLO Detect Delay vs. Ambient temperture

G/H/M/J/K/L Type, f_{osc}=1.2MHz



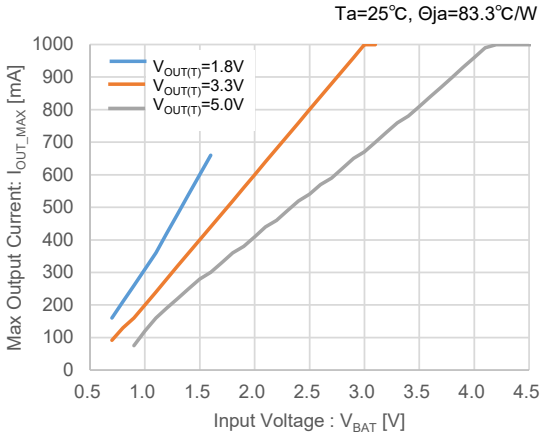
G/H/M/J/K/L Type, f_{osc}=3.0MHz



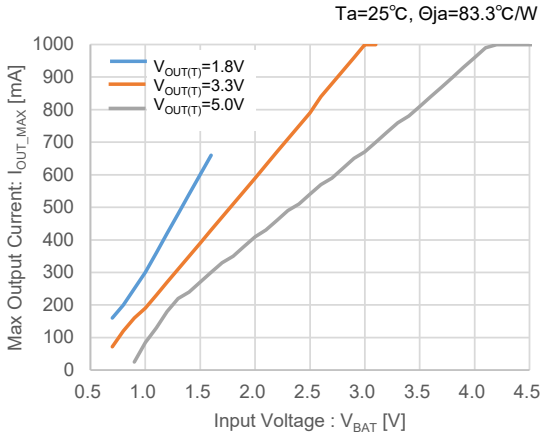
■TYPICAL PERFORMANCE CHARACTERISTICS

(27) Max Output Current vs. V_{BAT}

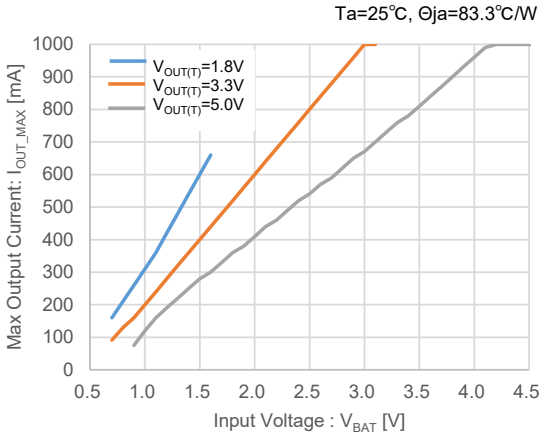
XC9147, f_{OSC}=1.2MHz



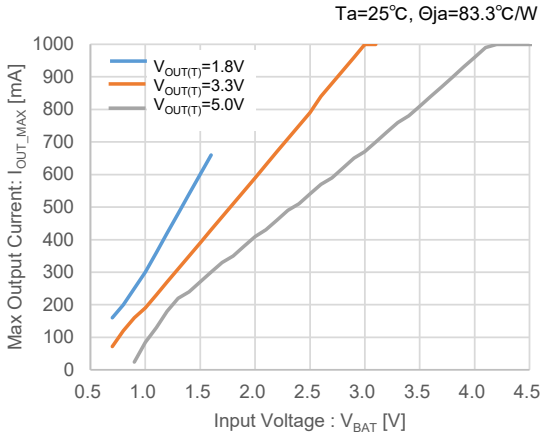
XC9147, f_{OSC}=3.0MHz



XC9148, f_{OSC}=1.2MHz



XC9148, f_{OSC}=3.0MHz

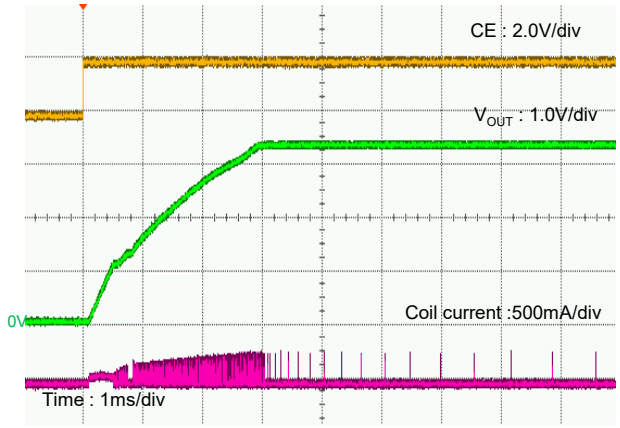


■TYPICAL PERFORMANCE CHARACTERISTICS

(28) Start-up Operation

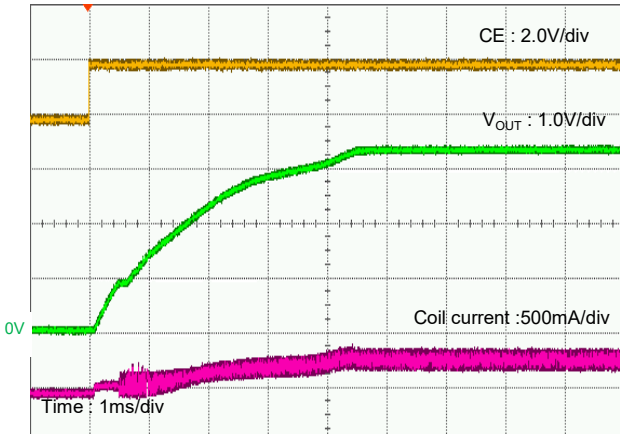
XC9148C33C ($V_{OUT(T)}$=3.3V, fosc=1.2MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=OPEN
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



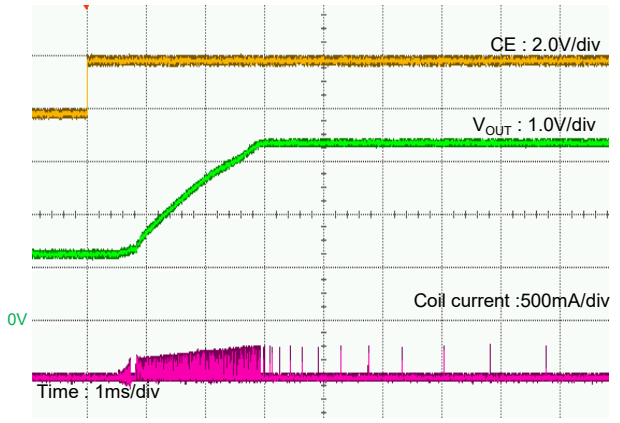
XC9148C33C ($V_{OUT(T)}$=3.3V, fosc=1.2MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=33Ω
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



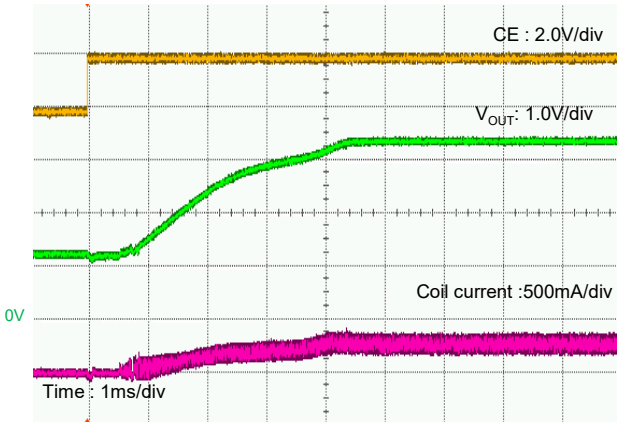
XC9148B33C ($V_{OUT(T)}$=3.3V, fosc=1.2MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=OPEN
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



XC9148B33C ($V_{OUT(T)}$=3.3V, fosc=1.2MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=33Ω
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)

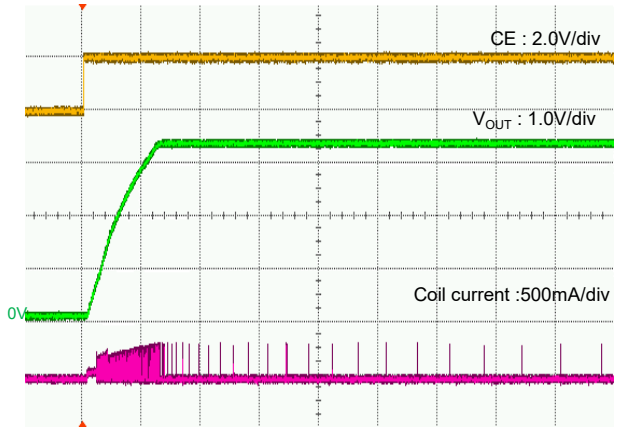


■TYPICAL PERFORMANCE CHARACTERISTICS

(28) Start-up Operation

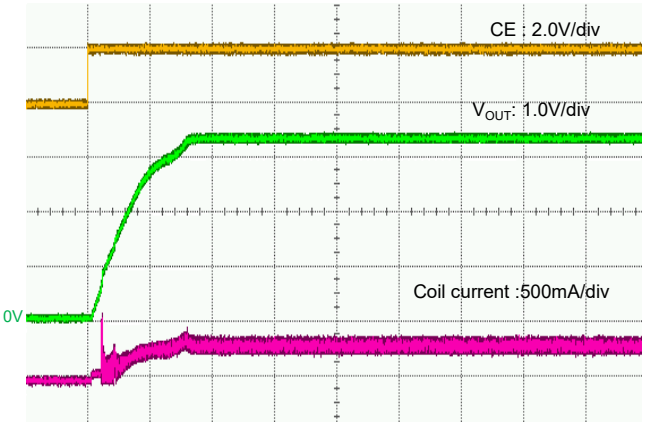
XC9148C33D ($V_{OUT(T)}$=3.3V, fosc=3.0MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=OPEN
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



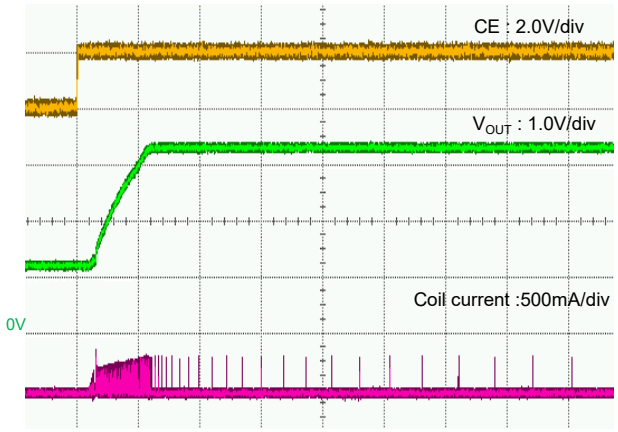
XC9148C33D ($V_{OUT(T)}$=3.3V, fosc=3.0MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=33Ω
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



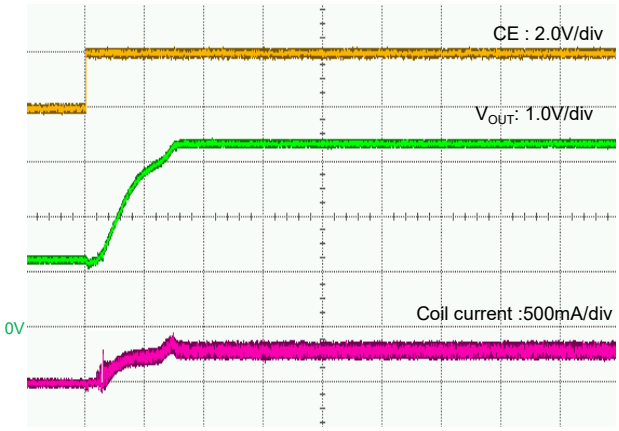
XC9148B33D ($V_{OUT(T)}$=3.3V, fosc=3.0MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=OPEN
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



XC9148B33D ($V_{OUT(T)}$=3.3V, fosc=3.0MHz)

V_{BAT}=1.2V,V_{OUT}=3.3V,RL=33Ω
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)

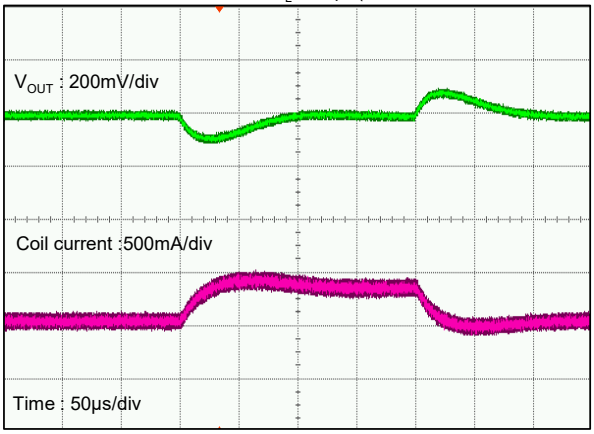


■TYPICAL PERFORMANCE CHARACTERISTICS

(29) Load Transient Response

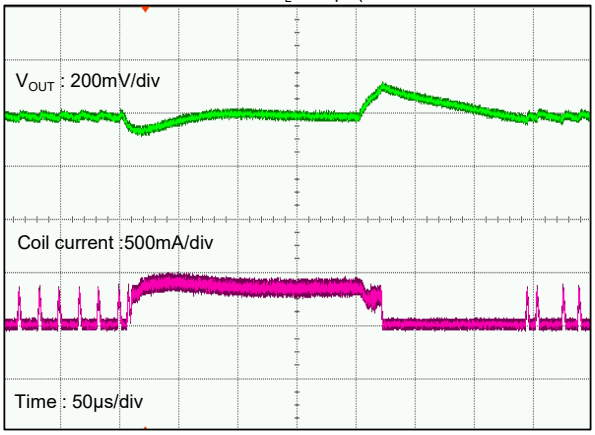
XC9147x18C ($V_{OUT(T)}$=1.8V, fosc=1.2MHz)

V_{BAT}=1.2V,V_{OUT}=1.8V,I_{OUT}=10mA⇔100mA(Tr=Tf=1us)
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



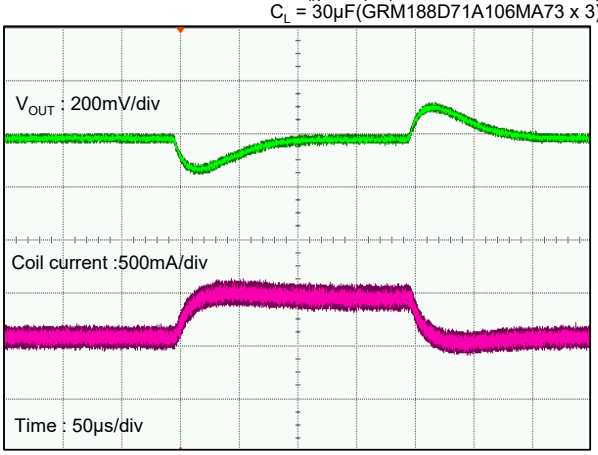
XC9148x18C ($V_{OUT(T)}$=1.8V, fosc=1.2MHz)

V_{BAT}=1.2V,V_{OUT}=1.8V,I_{OUT}=10mA⇔100mA(Tr=Tf=1us)
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



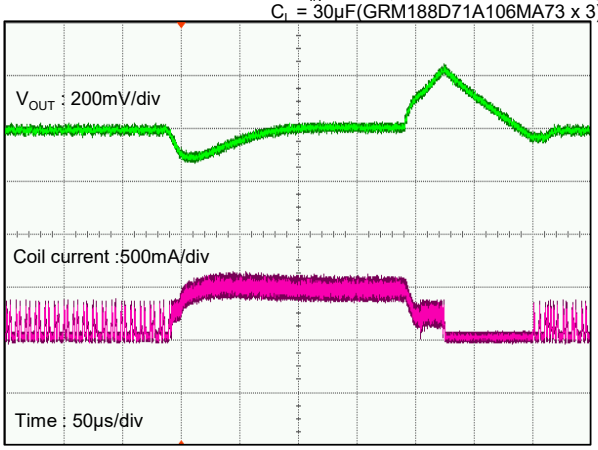
XC9147x33C ($V_{OUT(T)}$=3.3V, fosc=1.2MHz)

V_{BAT}=2.4V,V_{OUT}=3.3V,I_{OUT}=50mA⇔300mA(Tr=Tf=1us)
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



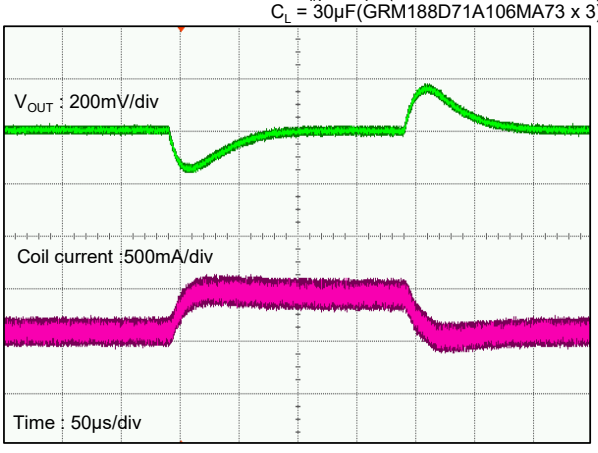
XC9148x33C ($V_{OUT(T)}$=3.3V, fosc=1.2MHz)

V_{BAT}=2.4V,V_{OUT}=3.3V,I_{OUT}=50mA⇔300mA(Tr=Tf=1us)
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



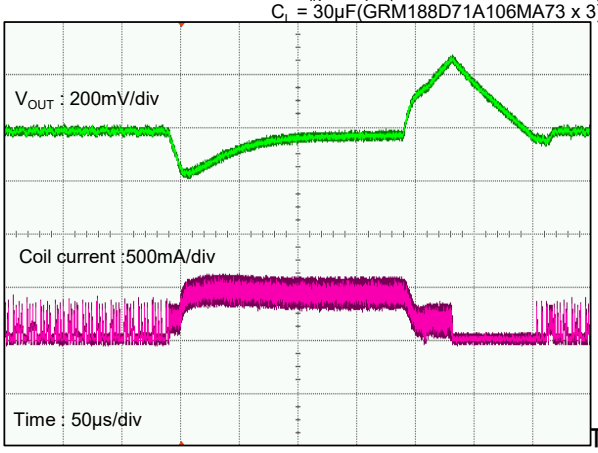
XC9147x50C ($V_{OUT(T)}$=5.0V, fosc=1.2MHz)

V_{BAT}=3.7V,V_{OUT}=5.0V,I_{OUT}=50mA⇔300mA(Tr=Tf=1us)
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)



XC9148x50C ($V_{OUT(T)}$=5.0V, fosc=1.2MHz)

V_{BAT}=3.7V,V_{OUT}=5.0V,I_{OUT}=50mA⇔300mA(Tr=Tf=1us)
L = 4.7μH(XFL4020-472ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 30μF(GRM188D71A106MA73 x 3)

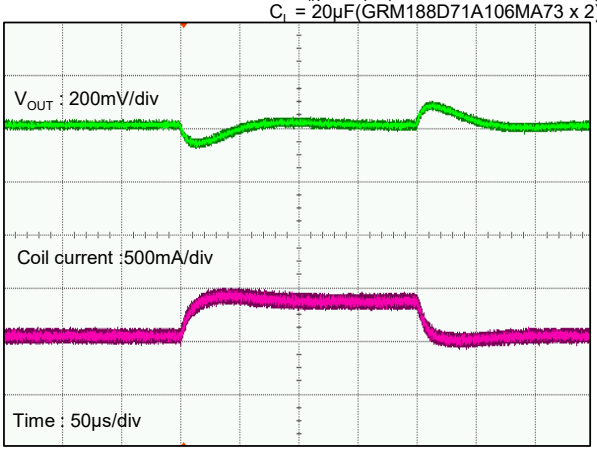


■TYPICAL PERFORMANCE CHARACTERISTICS

(29) Load Transient Response

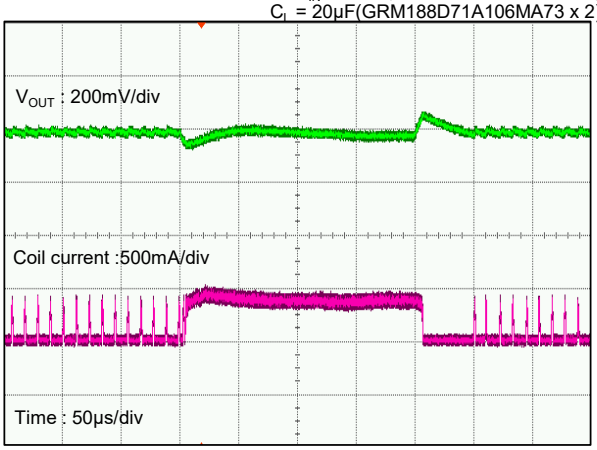
XC9147x18D ($V_{OUT(T)}$=1.8V, fosc=3.0MHz)

V_{BAT}=1.2V,V_{OUT}=1.8V,I_{OUT}=20mA⇔200mA(Tr=Tf=1us)
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



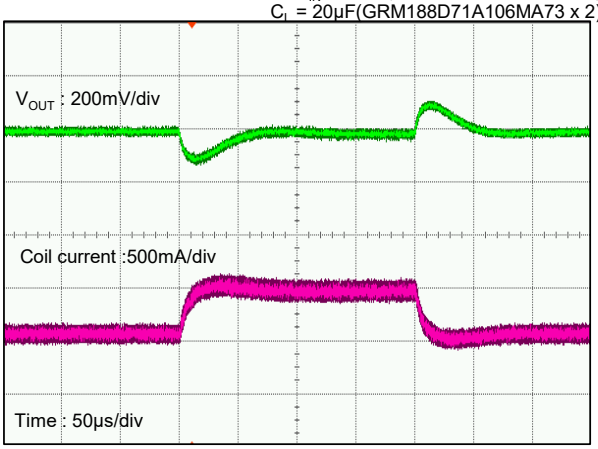
XC9148x18D ($V_{OUT(T)}$=1.8V, fosc=3.0MHz)

V_{BAT}=1.2V,V_{OUT}=1.8V,I_{OUT}=20mA⇔200mA(Tr=Tf=1us)
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



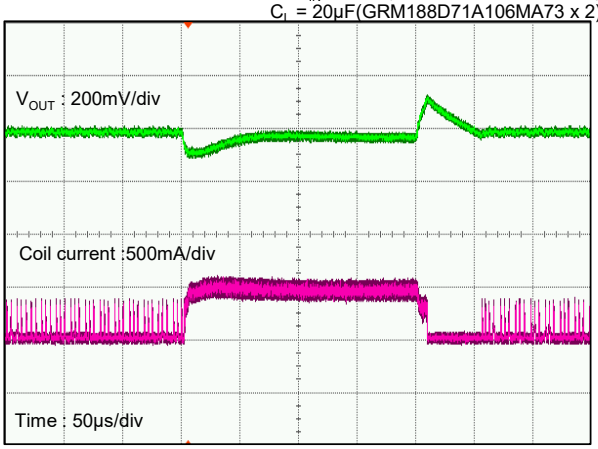
XC9147x33D ($V_{OUT(T)}$=3.3V, fosc=3.0MHz)

V_{BAT}=2.4V,V_{OUT}=3.3V,I_{OUT}=30mA⇔300mA(Tr=Tf=1us)
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



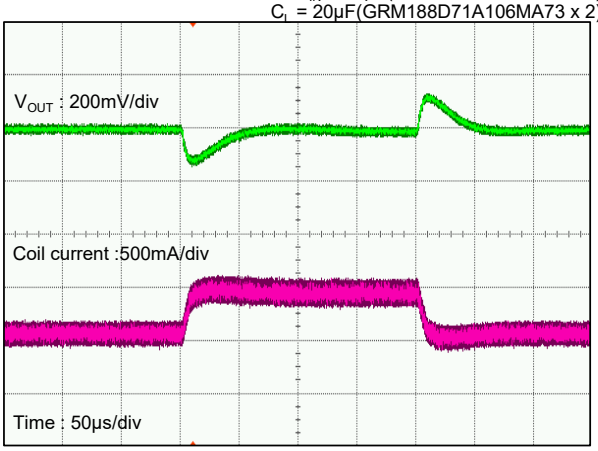
XC9148x33D ($V_{OUT(T)}$=3.3V, fosc=3.0MHz)

V_{BAT}=2.4V,V_{OUT}=3.3V,I_{OUT}=30mA⇔300mA(Tr=Tf=1us)
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



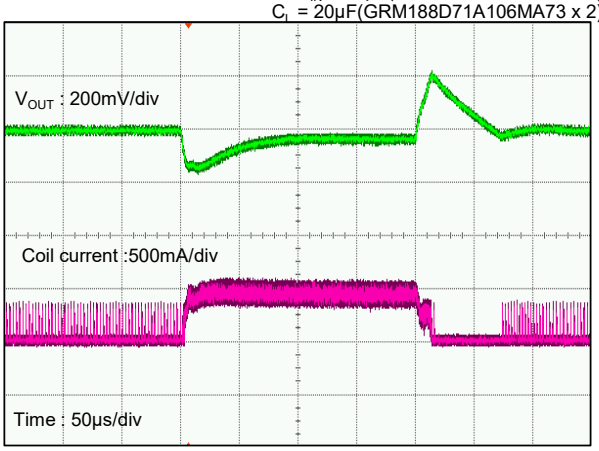
XC9147x50D ($V_{OUT(T)}$=5.0V, fosc=3.0MHz)

V_{BAT}=3.7V,V_{OUT}=5.0V,I_{OUT}=30mA⇔300mA(Tr=Tf=1us)
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



XC9148x50D ($V_{OUT(T)}$=5.0V, fosc=3.0MHz)

V_{BAT}=3.7V,V_{OUT}=5.0V,I_{OUT}=30mA⇔300mA(Tr=Tf=1us)
L = 2.2μH(XFL4020-222ME)
C_{IN} = 10μF(GRM188D71A106MA73)
C_L = 20μF(GRM188D71A106MA73 x 2)



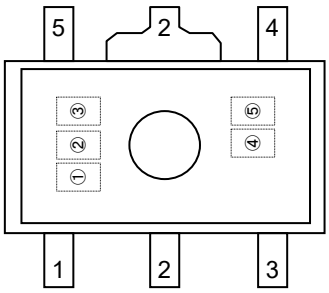
■PACKAGING INFORMATION

For the latest package information go to, www.torexsemi.com/technical-support/packages

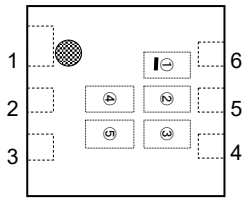
PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS
USP-6C	USP-6C PKG	USP-6C Power Dissipation
SOT-89-5	SOT-89-5 PKG	SOT-89-5 Power Dissipation

■MARKING RULE

SOT-89-5



USP-6C (with underline mark ①)



①represents product series and Oscillation Frequency

MARK	PRODUCT SERIES
P	XC9147***C**-G
R	XC9147***D**-G
S	XC9148***C**-G
T	XC9148***D**-G

②represents output voltage

MARK	TYPE	OUTPUT VOLTAGE RANGE	PRODUCT SERIES	PRODUCT SERIES	TYPE	OUTPUT VOLTAGE RANGE	PRODUCT SERIES
0	A	1.8～3.7	XC914*A*****-G	C	G	2.2～3.7	XC914*G*****-G
1		3.8～5.5		D		3.8～5.5	
2	B	1.8～3.7	XC9148B*****-G	E	H	2.2～3.7	XC9148H*****-G
3		3.8～5.5		F		3.8～5.5	
4	C	1.8～3.7	XC9148C*****-G	H	M	2.2～3.7	XC9148M*****-G
5		3.8～5.5		K		3.8～5.5	
6	D	2.2～3.7	XC914*D*****-G	L	J	2.2～3.7	XC914*J*****-G
7		3.8～5.5		M		3.8～5.5	
8	E	2.2～3.7	XC9148E*****-G	N	K	2.2～3.7	XC9148K*****-G
9		3.8～5.5		P		3.8～5.5	
A	F	2.2～3.7	XC9148F*****-G	R	L	2.2～3.7	XC9148L*****-G
B		3.8～5.5		T		3.8～5.5	

※B, C, E, F, H, M, K, L types are only available for XC9148 series.

③represents output voltage

MARK	OUTPUT VOLTAGE (V)		MARK	OUTPUT VOLTAGE (V)		MARK	OUTPUT VOLTAGE (V)	
0	1.8	3.8	7	2.5	4.5	E	3.2	5.2
1	1.9	3.9	8	2.6	4.6	F	3.3	5.3
2	2.0	4.0	9	2.7	4.7	H	3.4	5.4
3	2.1	4.1	A	2.8	4.8	K	3.5	5.5
4	2.2	4.2	B	2.9	4.9	L	3.6	-
5	2.3	4.3	C	3.0	5.0	M	3.7	-
6	2.4	4.4	D	3.1	5.1			

④、⑤represents production lot number

01～09, 0A～0Z, 11～9Z, A1～A9, AA～AZ, B1～ZZ in order.

(G, I, J, O, Q, W excluded. No character inversion used.)

1. The product and product specifications contained herein are subject to change without notice to improve performance characteristics. Consult us, or our representatives before use, to confirm that the information in this datasheet is up to date.

2. The information in this datasheet is intended to illustrate the operation and characteristics of our products. We neither make warranties or representations with respect to the accuracy or completeness of the information contained in this datasheet nor grant any license to any intellectual property rights of ours or any third party concerning with the information in this datasheet.

3. Applicable export control laws and regulations should be complied and the procedures required by such laws and regulations should also be followed, when the product or any information contained in this datasheet is exported.

4. The product is neither intended nor warranted for use in equipment of systems which require extremely high levels of quality and/or reliability and/or a malfunction or failure which may cause loss of human life, bodily injury, serious property damage including but not limited to devices or equipment used in 1) nuclear facilities, 2) aerospace industry, 3) medical facilities, 4) automobile industry and other transportation industry and 5) safety devices and safety equipment to control combustions and explosions. Do not use the product for the above use unless agreed by us in writing in advance.

5. Although we make continuous efforts to improve the quality and reliability of our products; nevertheless Semiconductors are likely to fail with a certain probability. So in order to prevent personal injury and/or property damage resulting from such failure, customers are required to incorporate adequate safety measures in their designs, such as system fail safes, redundancy and fire prevention features.

6. Our products are not designed to be Radiation-resistant.

7. Please use the product listed in this datasheet within the specified ranges.

8. We assume no responsibility for damage or loss due to abnormal use.

9.

TOREX SEMICONDUCTOR LTD.

单击下面可查看定价，库存，交付和生命周期等信息

>>Torex Semiconductor(特瑞仕)